### DATA SHEET

# μ**PD753012A, 753016A, 753017A**

## **4-BIT SINGLE-CHIP MICROCONTROLLER**

#### DESCRIPTION

EC

The  $\mu$ PD753017A is one of the 75XL series 4-bit single-chip microcontroller chips and has a data processing capability comparable to that of an 8-bit microcontroller.

It has an on-chip LCD controller/driver with a larger ROM capacity and extended CPU functions compared with the conventional  $\mu$ PD75316B, and can provide high-speed operation at a low supply voltage of 1.8 V. It can be supplied in a small plastic TQFP package (12 × 12 mm) and is suitable for small sets using LCD panels.

# Detailed descriptions of functions are provided in the following document. Be sure to read the document before designing. $\mu$ PD753017 User's Manual : U11282E

#### FEATURES

- Low voltage operation: VDD = 1.8 to 5.5 V
   Can be driven by two 1.5 V batteries
- On-chip memory
  - Program memory (ROM): 12288 × 8 bits (μPD753012A) 16384 × 8 bits (μPD753016A) 24576 × 8 bits (μPD753017A)
  - Data memory (RAM):
     1024 × 4 bits

- Capable of high-speed operation and variable instruction execution time for power saving
  - · 0.95, 1.91, 3.81, 15.3 μs (at 4.19 MHz operation)
  - · 0.67, 1.33, 2.67, 10.7 μs (at 6.0 MHz operation)
  - · 122 μs (at 32.768 kHz operation)
- Internal programmable LCD controller/driver
- Small plastic TQFP (12 × 12 mm)
   Suitable for small sets such as cameras
- One-time PROM: µPD75P3018A

#### APPLICATION

Remote controllers, camera-integrated VCRs, cameras, gas meters, etc.

In this document, unless otherwise specified, the description is made based on  $\mu$ PD753017A as typical product.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

#### ORDERING INFORMATION

	Part number	Package
	μPD753012AGC-XXX-3B9	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 2.7 mm)
*	$\mu$ PD753012AGC-XXX-8BT	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 1.4 mm)
	$\mu$ PD753012AGK-XXX-BE9	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.05 mm)
*	$\mu$ PD753012AGK-XXX-9EU	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.00 mm)
	μPD753016AGC-XXX-3B9	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 2.7 mm)
*	$\mu$ PD753016AGC-XXX-8BT	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 1.4 mm)
	$\mu$ PD753016AGK-XXX-BE9	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.05 mm)
*	$\mu$ PD753016AGK-XXX-9EU	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.00 mm)
	$\mu$ PD753017AGC-XXX-3B9	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 2.7 mm)
*	$\mu$ PD753017AGC-XXX-8BT	80-pin plastic QFP (14 $ imes$ 14 mm, resin thickness 1.4 mm)
	$\mu$ PD753017AGK-XXX-BE9	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.05 mm)
*	$\mu$ PD753017AGK-XXX-9EU	80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm, resin thickness 1.00 mm)

Remark XXX indicates ROM code suffix.

#### FUNCTION OUTLINE

Parameter				Function		
Instruction execution time		9	• 0	9.95, 1.91, 3.81, 15.3 $\mu$ s (main system clock: at 4.19 MHz operation) 9.67, 1.33, 2.67, 10.7 $\mu$ s (main system clock: at 6.0 MHz operation) 22 $\mu$ s (subsystem clock: at 32.768 kHz operation)		
Internal memory ROM			122	288 × 8 bits (μPD753012A)		
			163	84 × 8 bits (μPD753016A)		
			24576 × 8 bits (μPD753017A)			
		RAM	102	$4 \times 4$ bits		
General	purpose register			-bit operation: $8 \times 4$ banks -bit operation: $4 \times 4$ banks		
Input/ output port	CMOS input		8	On-chip pull-up resistors can be specified by using		
	CMOS input/o	utput	16	software: 23		
	CMOS output		8	Also used for segment pins		
	N-ch open-dra input/output	ain	8	Withstands 13 V, on-chip pull-up resistors can be specified by using mask option		
	Total	40				
LCD con	troller/driver		• D	Segment number selection: 24/28/32 segments (can be changed to CMOS output port in 4 time-unit; max. 8)Display mode selection: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)		
			On-chip split resistor for LCD drive can be specified by using mask option			
Timer			<ul> <li>5 channels</li> <li>8-bit timer/event counter: 3 channels (can be used for 16-bit timer/event counter, carrier generator, timer with gate)</li> <li>Basic interval timer/watchdog timer: 1 channel</li> <li>Watch timer: 1 channel</li> </ul>			
Serial int	erface		<ul> <li>3-wire serial I/O mode MSB or LSB can be selected for transferring first bit</li> <li>2-wire serial I/O mode</li> <li>SBI mode</li> <li>16 bits</li> </ul>			
Bit seque	ential buffer					
Clock ou	tput (PCL)		<ul> <li>Φ, 524, 262, 65.5 kHz (main system clock: at 4.19 MHz operation)</li> <li>Φ, 750, 375, 93.8 kHz (main system clock: at 6.0 MHz operation)</li> </ul>			
Buzzer output (BUZ)			<ul> <li>2, 4, 32 kHz (main system clock: at 4.19 MHz operation or subsystem clock: at 32.768 kHz operation)</li> <li>2.93, 5.86, 46.9 kHz (main system clock: at 6.0 MHz operation)</li> </ul>			
Vectored	interrupt		External: 3, Internal: 5			
Test inpu	ıt		Exte	ernal: 1, Internal: 1		
System of	clock oscillator		<ul> <li>Ceramic or crystal oscillator for main system clock oscillation</li> <li>Crystal oscillator for subsystem clock oscillation</li> </ul>			
Standby	function		STOP/HALT mode			
Power su	pply voltage		Vdd	= 1.8 to 5.5 V		
Package			<ul> <li>80-pin plastic QFP (14 × 14 mm)</li> <li>80-pin plastic TQFP (fine pitch) (12 × 12 mm)</li> </ul>			

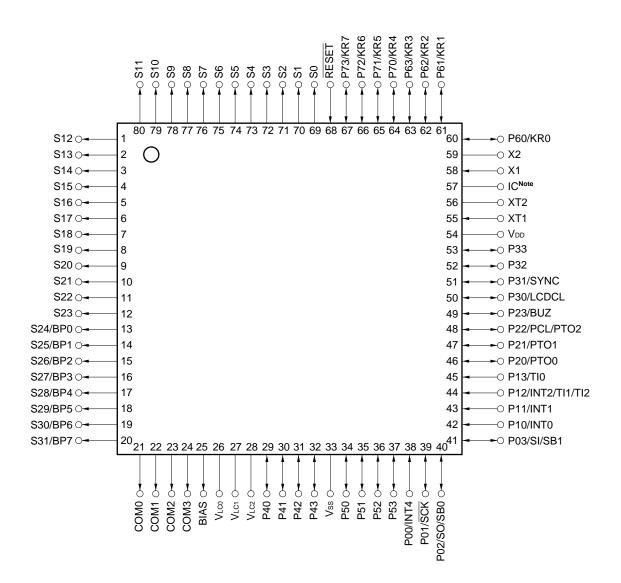
#### CONTENTS

	1.	PIN CONFIGURATION (Top View)	6
	2.	BLOCK DIAGRAM	8
	3.	PIN FUNCTION       9         3.1 Port Pins       9         3.2 Non-port Pins       11         3.3 Pin Input/Output Circuits       12         3.4 Recommended Connection for Unused Pins       14	9 1 3
	4.	SWITCHING FUNCTION BETWEEN Mk I MODE AND Mk II MODE	6
	5.	MEMORY CONFIGURATION	8
	6.	PERIPHERAL HARDWARE FUNCTIONS       23         6.1 Digital Input/Output Ports       23         6.2 Clock Generator       24         6.3 Subsystem Clock Oscillator Control Functions       24         6.4 Clock Output Circuit       26         6.5 Basic Interval Timer/Watchdog Timer       27         6.6 Watch Timer       22         6.7 Timer/Event Counter       22         6.8 Serial Interface       33         6.9 LCD Controller/Driver       33         6.10 Bit Sequential Buffer       33	3 4 5 6 7 8 9 3 5
	7.	INTERRUPT FUNCTION AND TEST FUNCTION	3
	8.	STANDBY FUNCTION	D
	9.	RESET FUNCTION	1
	10.	MASK OPTION	4
	11.	INSTRUCTION SET	5
	12.	ELECTRICAL SPECIFICATIONS	7
*	13.	CHARACTERISTICS CURVES (REFERENCE VALUES)	1
	14.	PACKAGE DRAWINGS	3
	15.	RECOMMENDED SOLDERING CONDITIONS	7

APPENDIX A.	μ <b>PD75316B, 753017A</b> Α	ND 75P3018A	FUNCTION	LIST	79
APPENDIX B.	DEVELOPMENT TOOL	S			31
APPENDIX C.	RELATED DOCUMENT	S			35

#### 1. PIN CONFIGURATION (Top View)

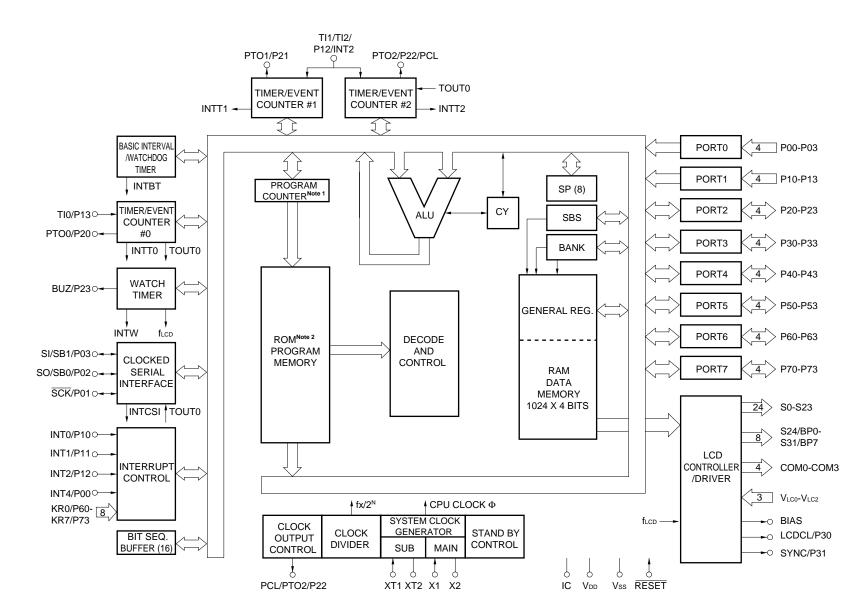
- 80-pin plastic QFP (14 × 14 mm)
- μPD753012AGC-XXX-3B9, 753012AGC-XXX-8BT, 753016AGC-XXX-3B9, 753016AGC-XXX-8BT
   μPD753017AGC-XXX-3B9, 753017AGC-XXX-8BT
  - 80-pin plastic TQFP (fine pitch) ( $12 \times 12$  mm)
- μPD753012AGK-XXX-BE9, 753012AGK-XXX-9EU, 753016AGK-XXX-BE9, 753016AGK-XXX-9EU
   μPD753017AGK-XXX-BE9, 753017AGK-XXX-9EU

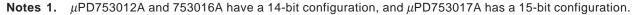


Note Connect the IC (Internally Connected) pin directly to VDD.

# NEC

Pin Identification	Pin Identification								
BIAS	: LCD Power Supply Bias Control	PCL	: Programmable Clock						
BP0-BP7	: Bit Port	PTO0-PTO2	: Programmable Timer Output 0-2						
BUZ	: Buzzer Clock	RESET	:Reset Input						
COM0-COM3	: Common Output 0-3	S0-S31	: Segment Output 0-31						
IC	: Internally Connected	SB0, SB1	: Serial Bus 0, 1						
INTO, INT1, INT4	: External Vectored Interrupt 0, 1, 4	SCK	: Serial Clock						
INT2	: External Test Input 2	SI	: Serial Input						
KR0-KR7	:Key Return	SO	: Serial Output						
LCDCL	: LCD Clock	SYNC	: LCD Synchronization						
P00-P03	: Port 0	TI0-TI2	: Timer Input 0-2						
P10-P13	: Port 1	Vdd	: Positive Power Supply						
P20-P23	: Port 2	VLC0-VLC2	: LCD Power Supply 0-2						
P30-P33	: Port 3	Vss	: Ground						
P40-P43	: Port 4	X1, X2	: Main System Clock Oscillation 1, 2						
P50-P53	: Port 5	XT1, XT2	: Subsystem Clock Oscillation 1, 2						
P60-P63	: Port 6								
P70-P73	: Port 7								





2. Capacity of the ROM depends on the product.

 $\mu$ PD753012A, 753016A, 753017A

# 2. BLOCK DIAGRAM

Z

#### 3. PIN FUNCTION

#### 3.1 Port Pins (1/2)

Pin Name	I/O	Alternate Function	Function	8-bit I/O	After Reset	I/O Circuit Type <sup>Note 1</sup>
P00	Input	INT4			Input	<b></b>
P01		SCK	For P01 to P03, connection of on-chip pull- up resistors can be specified by software in			<f>-A</f>
P02		SO/SB0	3-bit units.			<f>-B</f>
P03		SI/SB1	-			<m>-C</m>
P10	Input	INT0	4-bit input port (PORT1).	No	input	<b>-C</b>
P11		INT1	Connection of on-chip pull-up resistors can			
P12		TI1/TI2/INT2	be specified by software in 4-bit units. Only P10/INT0 can select noise elimination circuit.			
P13		TIO				
P20	I/O	PTO0	· · · · · · · · · · · · · · · · · · ·	No	Input	E-B
P21		PTO1	Connection of on-chip pull-up resistors can			
P22		PCL/PTO2	be specified by software in 4-bit units.			
P23		BUZ				
P30	I/O	LCDCL	Programmable 4-bit input/output port	No	Input	E-B
P31		SYNC	(PORT3). This port can be specified for input/output			
P32		_	bit-wise.			
P33		_	bit-wise. Connection of on-chip pull-up resistor can be specified by software in 4-bit units.			
P40-P43 <sup>Note 2</sup>	I/O	_	N-ch open-drain 4-bit input/output port (PORT4). A pull-up resistor can be contained bit-wise (mask option). Withstand voltage is 13 V in open-drain mode.	Yes	High level (when pull- up resistors are provided) or high impedance	M-D
P50-P53 <sup>Note 2</sup>	I/O	_	N-ch open-drain 4-bit input/output port (PORT5). A pull-up resistor can be contained bit-wise (mask option). Withstand voltage is 13 V in open-drain mode.		High level (when pull- up resistors are provided) or high impedance	M-D

Notes 1. Circuit types enclosed in brackets indicate the Schmitt trigger input.

2. If on-chip pull-up resistors are not specified by mask option (when used as N-ch open-drain input port), low level input leakage current increases when input or bit manipulation instruction is executed.

\* \*

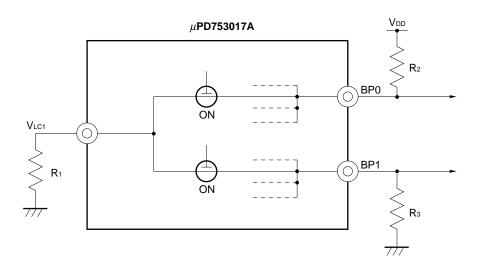
#### 3.1 Port Pins (2/2)

Pin Name	I/O	Alternate Function	Function	8-bit I/O	After Reset	I/O Circuit Type <sup>Note 1</sup>
P60	I/O	KR0	Programmable 4-bit input/output port (PORT6). This port can be specified for input/output bit-wise. Connection of on-chip pull-up resistors can be specified by software in 4-bit units.		Input	<f>-A</f>
P61		KR1				
P62		KR2				
P63		KR3				
P70	I/O	KR4	4-bit input/output port (PORT7). Connection of on-chip pull-up resistors can be specified by software in 4-bit units.		Input	<f>-A</f>
P71		KR5				
P72		KR6				
P73		KR7				
BP0	Output	S24	1-bit output port (BIT PORT).	No	Note 2	H-A
BP1		S25 Also used for segment output pins.				
BP2		S26				
BP3		S27				
BP4	Output	S28				
BP5		S29				
BP6		S30				
BP7		S31				

Notes 1. Circuit types enclosed in brackets indicate the Schmitt trigger input.

 BP0 through BP7 select VLC1 as an input source. However, the output levels change depending on the external circuit of BP0 through BP7 and VLC1.

**Example** Because BP0 through BP7 are mutually connected inside the  $\mu$ PD753017A, the output levels of BP0 through BP7 are determined by R<sub>1</sub>, R<sub>2</sub>, and R<sub>3</sub>.



#### 3.2 Non-port Pins (1/2)

Pin Name	I/O	Alternate Function	Function		After Reset	I/O Circuit Type <sup>Note 1</sup>
Т10	Input	P13	Inputs external event pulses to	the timer/event	Input	<b>-C</b>
TI1		P12/INT2	counter.			
TI2						
PTO0	Output	P20	Timer/event counter output		Input	E-B
PTO1		P21				
PTO2		P22/PCL				
PCL		P22/PTO2	Clock output	Clock output		
BUZ		P23	Optional frequency output (for l or system clock trimming)	buzzer output		
SCK	I/O	P01	Serial clock input/output		Input	<f>-A</f>
SO/SB0		P02	Serial data output Serial data bus input/output			<f>-B</f>
SI/SB1		P03	Serial data input Serial data bus input/output			<m>-C</m>
INT4	Input	P00	Edge detection vectored interrupt input (both rising edge and falling edge detection)		Input	<b></b>
INT0	Input	P10	Edge detection vectored interrupt input (detection edge can be selected)	Noise elimination circuit/asynchronous selection	Input	<b>-C</b>
INT1		P11	INT0/P10 can select noise elimination circuit.	Asynchronous		
INT2	Input	P12/TI1/TI2	Rising edge detection testable input	Asynchronous	Input	<b>-C</b>
KR0-KR3	Input	P60-P63	Falling edge detection testable	input	Input	<f>-A</f>
KR4-KR7	Input	P70-P73	Falling edge detection testable	input	Input	<f>-A</f>
S0-S23	Output	-	Segment signal output		Note 2	G-A
S24-S31	Output	BP0-BP7	Segment signal output		Note 2	H-A
COM0-COM3	Output	-	Common signal output		Note 2	G-B
VLC0-VLC2	-	-	LCD drive power On-chip split resistor is enable (mask option).		-	-
BIAS	Output	-	Output for external split resistor	disconnect	Note 3	_
LCDCL <sup>Note 4</sup>	Output	P30	Clock output for externally expa	anded driver	Input	E-B
SYNC <sup>Note 4</sup>	Output	P31	Clock output for externally expansion	nded driver	Input	E-B

Notes 1. Circuit types enclosed in brackets indicate the Schmitt trigger input.

- Each display output selects the following VLCX as input source. S0-S31: VLC1, COM0-COM2: VLC2, COM3: VLC0
- **3.** When a split resistor is contained ...... Low level When no split resistor is contained ..... High impedance
- **4.** These pins are provided for future system expansion. At present, these pins are used only as pins P30 and P31.

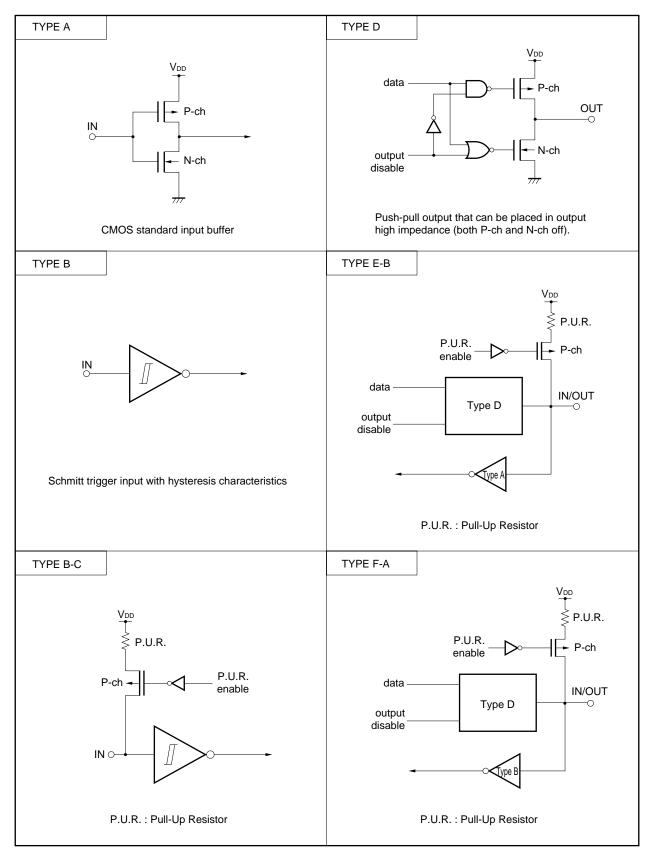
#### 3.2 Non-port Pins (2/2)

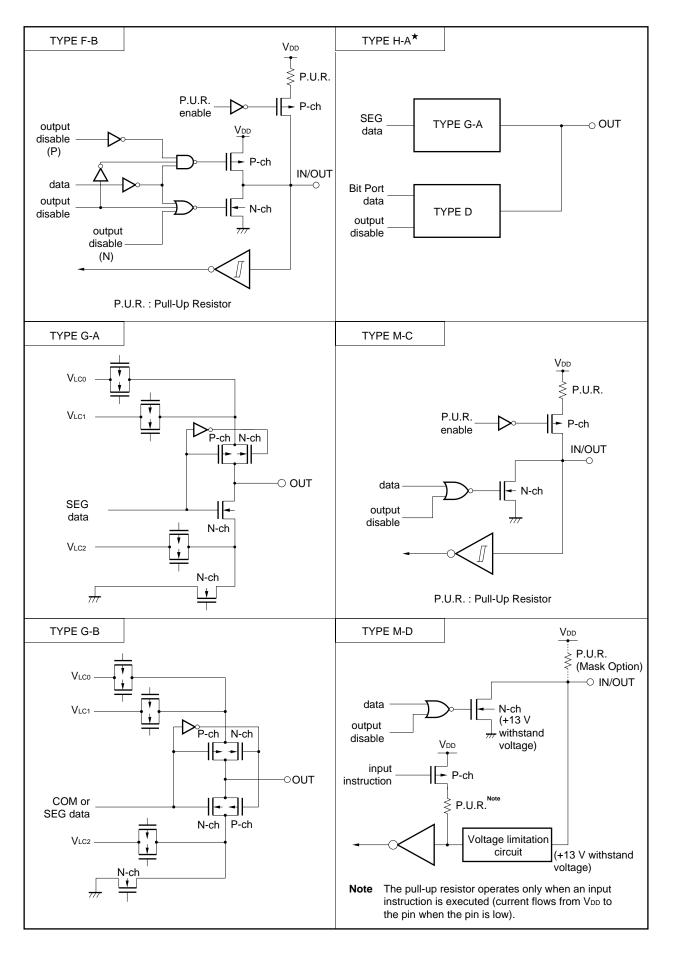
Pin Name	I/O	Alternate Function	Function	After Reset	I/O Circuit Type <sup>Note</sup>
X1	Input	_	Crystal/ceramic connection pin for the mainsystem	_	_
X2	_	_	clock oscillation. When inputting the external clock, input the external clock to pin X1, and the inverted phase of the external clock to pin X2.		
XT1	Input	-	Crystal connection pin for the subsystem clock	_	_
XT2	-		oscillation. When the external clock is used, input the external clock to pin XT1, and the inverted phase of the external clock to pin XT2. Pin XT1 can be used as a 1-bit input (test) pin.		
RESET	Input	-	System reset input (low level active)	-	<b></b>
IC	-	_	Internally connected. Connect directly to VDD.	-	_
Vdd	-	-	Positive power supply	-	-
Vss	-	-	GND	_	_

Note Circuit types enclosed in brackets indicate the Schmitt trigger input.

#### 3.3 Pin Input/Output Circuits

The  $\mu$ PD753017A pin input/output circuits are shown schematically.





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#### 3.4 Recommended Connection for Unused Pins

Pin	Recommended Connection
P00/INT4	Connect to Vss or VDD
P01/SCK	Connect to Vss or VDD via a resistor individually
P02/SO/SB0	
P03/SI/SB1	Connect to Vss
P10/INT0, P11/INT1	Connect to Vss or VDD
P12/TI1/TI2/INT2	
P13/TI0	
P20/PTO0	Input: Connect to Vss or Vbb via a resistor individually
P21/PTO1	Output: Leave open
P22/PTO2/PCL	
P23/BUZ	
P30/LCDCL	
P31/SYNC	
P32	
P33	
P40-P43	Input: Connect to Vss
P50-P53	Output: Connect to Vss (do not connect a pull-up resistor of mask option)
P60/KR0-P63/KR3	Input: Connect to Vss or Vbb via a resistor individually
P70/KR4-P73/KR7	Output: Leave open
S0-S23	Leave open
S24/BP0-S31/BP7	
COM0-COM3	
VLC0-VLC2	Connect to Vss
BIAS	Only if all of $V_{LC0}$ - $V_{LC2}$ are unused, connect to $V_{SS}$ . In other cases, leave open.
XT1	Connect to Vss
XT2 <sup>Note</sup>	Leave open
IC	Connect to VDD directly

#### Table 3-1. List of Recommended Connection for Unused Pins

**Note** When the subsystem clock is not used, set SOS.0 to 1 (so as not to use the internal feedback resistor).

#### 4. SWITCHING FUNCTION BETWEEN Mk I MODE AND Mk II MODE

#### 4.1 Differences between Mk I Mode and Mk II Mode

The CPU of  $\mu$ PD753017A has the following two modes: Mk I and Mk II, either of which can be selected. The mode can be switched by the bit 3 of the stack bank select register (SBS).

- Mk I mode: Upward compatible with μPD75316B.
   Can be used in the 75XL CPU with a ROM capacity of up to 16K bytes.
- Mk II mode: Incompatible with μPD75316B.
   Can be used in all the 75XL CPU's including those products whose ROM capacity is more than 16K bytes.

	Mk I Mode	Mk II Mode
Program memory (bytes)	<ul> <li>μPD753012A : 12288</li> <li>μPD753016A, 753017A : 16384</li> </ul>	<ul> <li>μPD753012A : 12288</li> <li>μPD753016A : 16384</li> <li>μPD753017A : 24576</li> </ul>
Number of stack bytes for subroutine instructions	2 bytes	3 bytes
BRA !addr1 instruction CALLA !addr1 instruction	Not available	Available
CALL laddr instruction	3 machine cycles	4 machine cycles
CALLF !faddr instruction	2 machine cycles	3 machine cycles

Table 4-1. Differences between Mk I Mode and Mk II Mode

Caution The Mk II mode supports a program area exceeding 16 Kbytes for the 75X and 75XL series. Therefore, this mode is effective for enhancing software compatibility with products exceeding 16 Kbytes.

When the Mk II mode is selected, the number of stack bytes used during execution of subroutine call instructions increases by one byte per stack compared to the Mk I mode. When the CALL !addr and CALLF !faddr instructions are used, the machine cycle becomes longer by one machine cycle. Therefore, use the Mk I mode if the RAM efficiency and processing performance are more important than software compatibility.

#### 4.2 Setting Method of Stack Bank Select Register (SBS)

Switching between the Mk I mode and Mk II mode can be done by the stack bank select register (SBS). Figure 4-1 shows the format.

The SBS is set by a 4-bit memory manipulation instruction. When using the Mk I mode, the SBS must be initialized to 10XXB<sup>Note</sup> at the beginning of a program. When using the Mk II mode, it must be initialized to 00XXB<sup>Note</sup>.

**Note** Set the desired value in the XX positions.

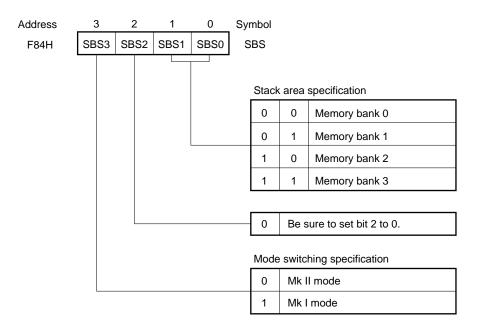


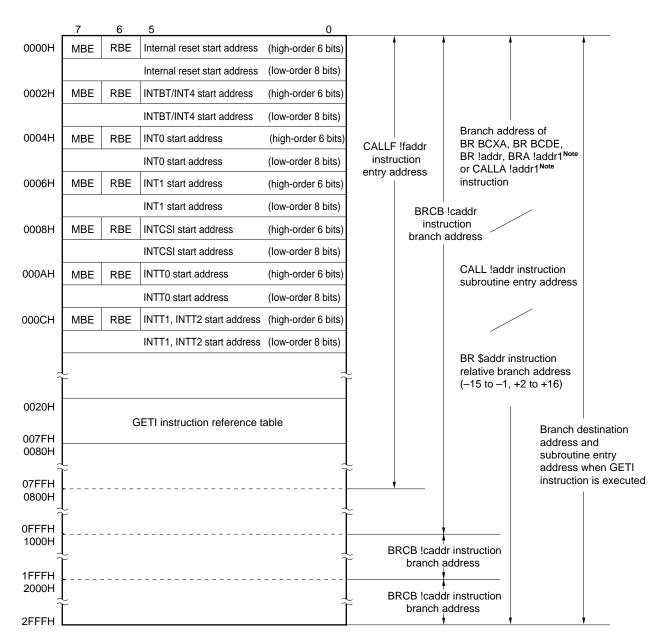
Figure 4-1. Stack Bank Select Register Format

Caution Since SBS. 3 is set to "1" after a RESET signal is generated, the CPU operates in the Mk I mode. When executing an instruction in the Mk II mode, set SBS. 3 to "0" to select the Mk II mode.

#### 5. MEMORY CONFIGURATION

- - Addresses 0000H and 0001H
     Vector table wherein the program start address and the values set for the RBE and MBE at the time a RESET signal is generated are written. Reset start is possible from any address.
  - Addresses 0002H to 000DH
     Vector table wherein the program start address and the values set for the RBE and MBE by each vectored interrupt are written. Interrupt processing can start from any address.
  - Addresses 0020H to 007FH
     Table area referenced by the GETI instruction<sup>Note</sup>.
    - **Note** The GETI instruction realizes a 1-byte instruction on behalf of any 2-byte/3-byte instruction, or two 1-byte instructions. It is used to decrease the number of program steps.
- Data memory (RAM)
  - Data area ...1024 words × 4 bits (000H to 3FFH)
  - Peripheral hardware area...128  $\times$  4 bits (F80H to FFFH)

#### Figure 5-1. Program Memory Map (1/3)

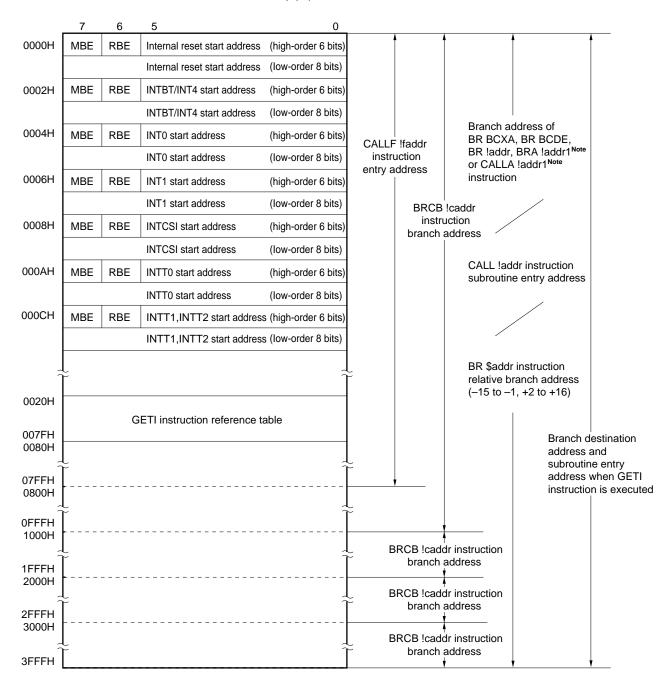


(a) μPD753012A

**Note** Can be used only in the Mk II mode.

**Remark** In addition to the above, a branch can be taken to the address indicated by changing only the low-order 8 bits of PC by executing the BR PCDE, BR PCXA instruction.

#### Figure 5-1. Program Memory Map (2/3)

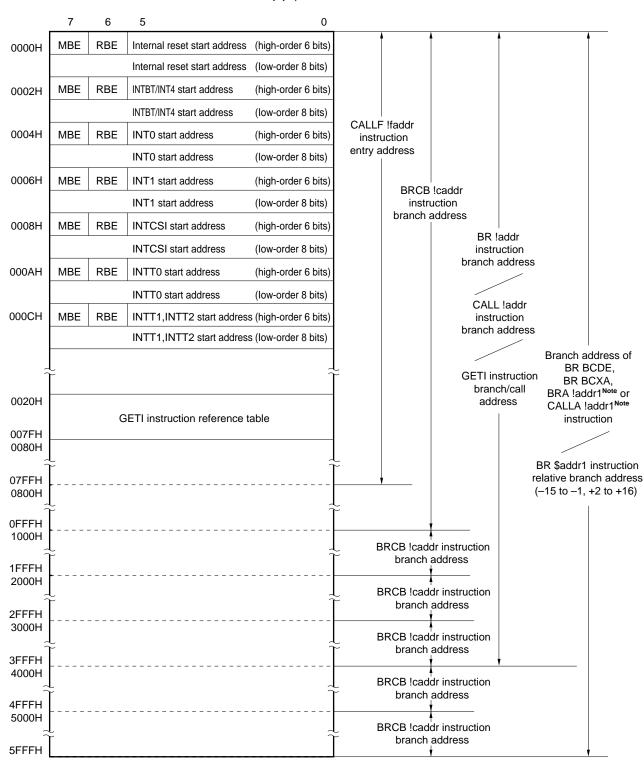


(b) µPD753016A

Note Can be used only in the Mk II mode.

**Remark** In addition to the above, a branch can be taken to the address indicated by changing only the low-order 8 bits of PC by executing the BR PCDE, BR PCXA instruction.

#### Figure 5-1. Program Memory Map (3/3)

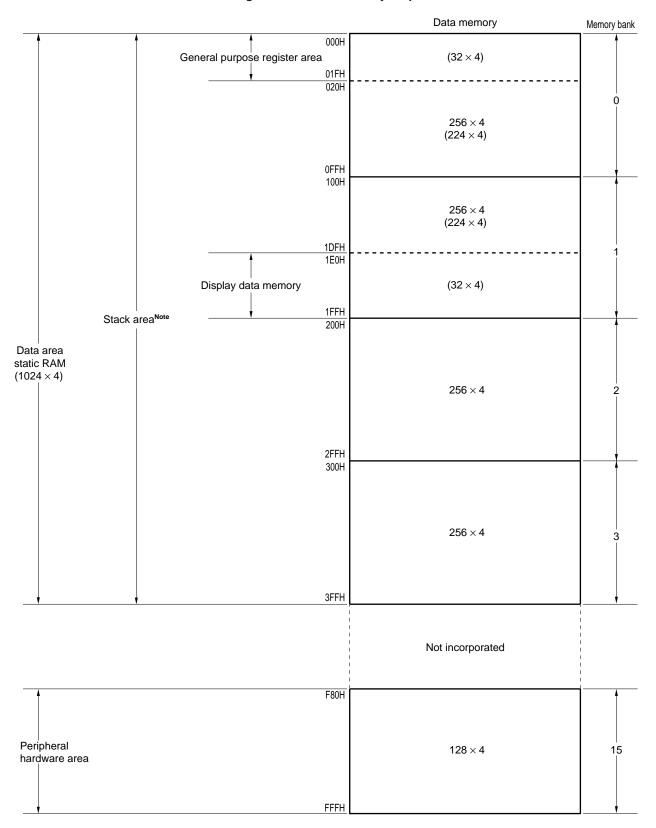


#### (c) μPD753017A

Note Can be used only in the Mk II mode.

Caution The interrupt vector start address shown above consists of 14 bits. Set it in 16K space (0000H-3FFFH).

**Remark** In addition to the above, a branch can be taken to the address indicated by changing only the low-order 8 bits of PC by executing the BR PCDE, BR PCXA instruction.



#### Figure 5-2. Data Memory Map

**Note** For stack area, one memory bank can be selected among memory banks 0 to 3.

#### 6. PERIPHERAL HARDWARE FUNCTIONS

#### 6.1 Digital Input/Output Ports

There are four types of I/O ports as follows.

· CMOS input (PORT0, 1)	:		8
· CMOS input/output (PORT2, 3, 6, 7)	:	1	6
<ul> <li>N-channel open-drain input/output (PORT4, 5)</li> </ul>	:		8
· Bit port output (BP0-BP7)	:		8
Total		4	0

Port (Pin Name)	Function	Operation and Features		Remarks	
PORT0 (P00-P03)	4-bit input	When the serial interface fu function pins function as ou operation mode.	Also used for the INT4, SCK, SO/SB0, SI/SB1 pins.		
PORT1 (P10-P13)		Input-only port		Also used for the INT0- INT2 and TI0-TI2 pins.	
PORT2 (P20-P23)	4-bit I/O	Can be set to input mode or output mode in 4-bit units.		Also used for the PTO0- PTO2, PCL, BUZ pins.	
PORT3 (P30-P33)		Can be set to input mode or output mode in 1/4-bit units.		Also used for the LCDCL, SYNC pins.	
PORT4 (P40-P43)	4-bit I/O (N-channel open-drain, 13 V withstanding)	(N-channel	Can be set to input mode or output mode in 4-bit units.	Ports 4 and 5 are paired and data can be input/ output in 8-bit units.	On-chip pull-up resistor can be specified bit-wise by mask option.
PORT5 (P50-P53)		units.	ouput in o bit units.		
PORT6 (P60-P63)	4-bit I/O	Can be set to input mode or output mode in 1/4-bit units.	Ports 6 and 7 are paired and data can be input/ output in 8-bit units.	Also used for the KR0-KR3 pins.	
PORT7 (P70-P73)	1	Can be set to input mode or output mode in 4-bit units.		Also used for the KR4-KR7 pins.	
BP0-BP7	1-bit output	Outputs data bit-wise. Can be switched to LCD drive segment output S24-S31 by software.		_	

#### Table 6-1. Types and Features of Digital Ports

#### 6.2 Clock Generator

Operation of the clock generator is determined by the processor clock control register (PCC) and system clock control register (SCC).

The two clocks, the main system clock and subsystem clock, are available.

The instruction excution time can be altered.

- 0.95  $\mu$ s, 1.91  $\mu$ s, 3.81  $\mu$ s, 15.3  $\mu$ s (main system clock : at 4.19 MHz operation)
- + 0.67  $\mu s,$  1.33  $\mu s,$  2.67  $\mu s,$  10.7  $\mu s$  (main system clock : at 6.0 MHz operation)
- 122  $\mu$ s (subsystem clock : at 32.768 kHz operation)

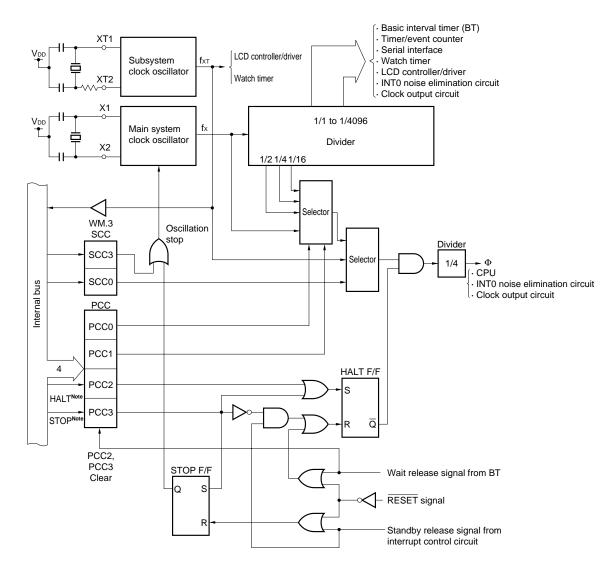


Figure 6-1. Clock Generator Block Diagram

Note Instruction execution

**Remarks 1.** fx = Main system clock frequency

- 2. fxt = Subsystem clock frequency
- 3.  $\Phi = CPU clock$
- 4. PCC: Processor Clock Control Register
- 5. SCC: System Clock Control Register
- 6. One clock cycle (tcr) of  $\Phi$  equal to one machine cycle of the instruction.

#### 6.3 Subsystem Clock Oscillator Control Functions

The  $\mu$ PD753017A subsystem clock oscillator has the following two control functions.

- Selects by software whether an internal feedback resistor is to be used or not<sup>Note</sup>.
- Reduces current consumption by decreasing the drive current of the on-chip inverter when the supply voltage is high (V<sub>DD</sub> ≥ 2.7 V).
  - **Note** When the subsystem clock is not used, set SOS.0 to 1 (so as not to use the internal feedback resistor) by software, connect XT1 to Vss, and open XT2. This makes it possible to reduce the current consumption in the subsystem clock oscillator.

The above functions can be used by switching the bits 0 and 1 of the sub-oscillator control register (SOS). (See Figure 6-2.)

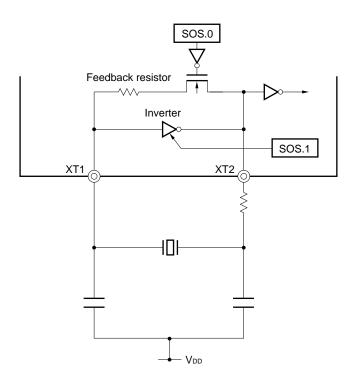
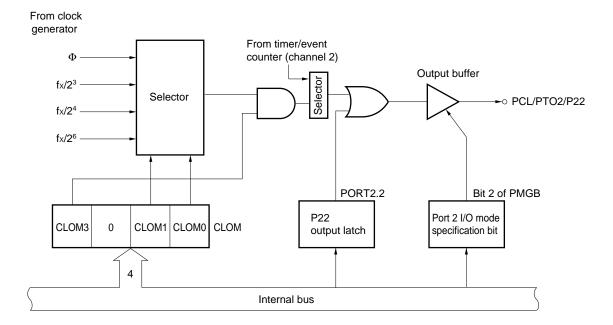


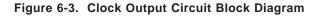
Figure 6-2. Subsystem Clock Oscillator

#### 6.4 Clock Output Circuit

The clock output circuit is provided to output the clock pulses from the P22/PTO2/PCL pin to the application of remote control wave outputs and peripheral LSI's.

Clock output (PCL) : Φ, 524, 262, 65.5 kHz (at 4.19 MHz operation)
 Φ, 750, 375, 93.8 kHz (at 6.0 MHz operation)



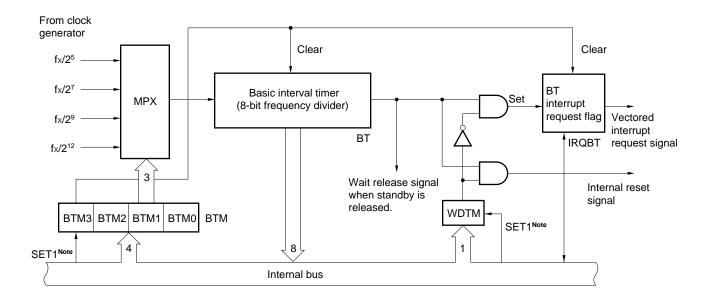


**Remark** Special care has been taken in designing the chip so that small-width pulses may not be output when switching clock output enable/disable.

#### 6.5 Basic Interval Timer/Watchdog Timer

The basic interval timer/watchdog timer has the following functions.

- Interval timer operation to generate a reference time interrupt
- · Watchdog timer operation to detect a runaway of program and reset the CPU
- · Selects and counts the wait time when the standby mode is released
- Reads the contents of counting





**Note** Instruction execution

#### 6.6 Watch Timer

The  $\mu$ PD753017A has one channel of watch timer. The watch timer has the following functions.

- Sets the test flag (IRQW) with 0.5 sec interval. The standby mode can be released by the IRQW.
- 0.5 sec interval can be created by both the main system clock (4.19 MHz) and subsystem clock (32.768 kHz).
- Convenient for program debugging and checking as interval becomes 128 times longer (3.91 ms) with the fast feed mode.
- Outputs the frequencies (2.048, 4.096, 32.768 kHz) to the P23/BUZ pin, usable for buzzer and trimming of system clock oscillation frequencies.
- Clears the frequency divider to make the clock start with zero seconds.

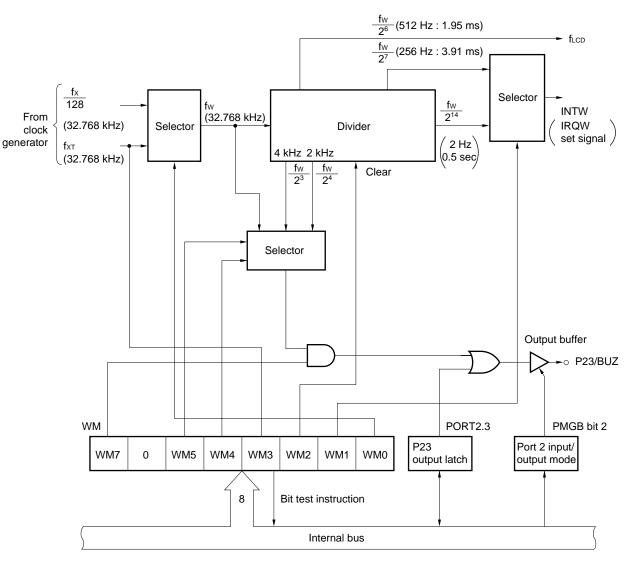


Figure 6-5. Watch Timer Block Diagram

The values enclosed in parentheses are applied when  $f_x = 4.19$  MHz and  $f_{xT} = 32.768$  kHz.

#### 6.7 Timer/Event Counter

The  $\mu$ PD753017A has three channels of timer/event counter. The timer/event counter has the following functions.

- Programmable interval timer operation
- Square wave output of any frequency to the PTOn pin (n = 0, 1)
- Event counter operation
- Divides the frequency of signal input via the TIn pin to 1-Nth of the original signal and outputs the divided frequency to the PTOn pin (frequency division operation).
- Supplies the shift clock to the serial interface circuit (channel 0 only).
- Calls the count value.

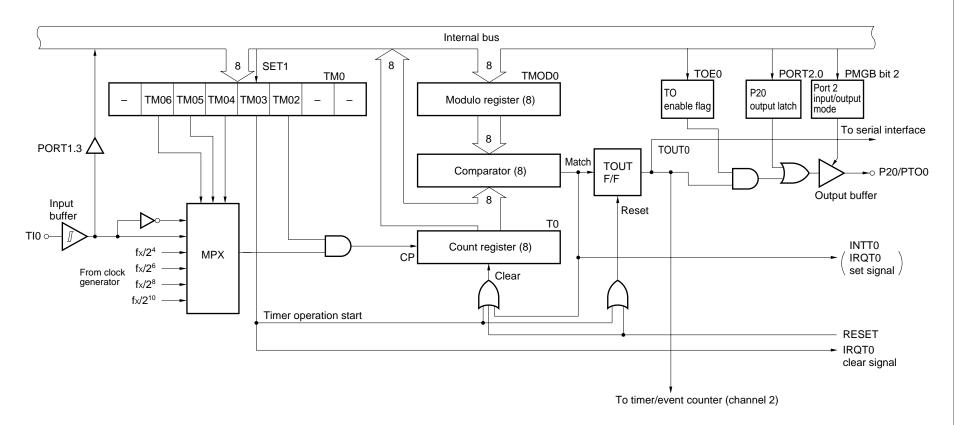
The timer/event counter operates in the following four modes as set by the mode register.

	Channel	Channel 0	Channel 1	Channel 2
Mode				
8-bit timer/event	Yes	Yes	Yes	
	Gate control function	No <sup>Note</sup>	No	Yes
PWM pulse gene	No	No	Yes	
16-bit timer/even	No	Yes		
	Gate control function	No <sup>Note</sup>	Yes	
Carrier generator	No	Yes		

Table 6-2. Operation Modes of Timer/Event Counter

**Note** Used for gate control signal generation

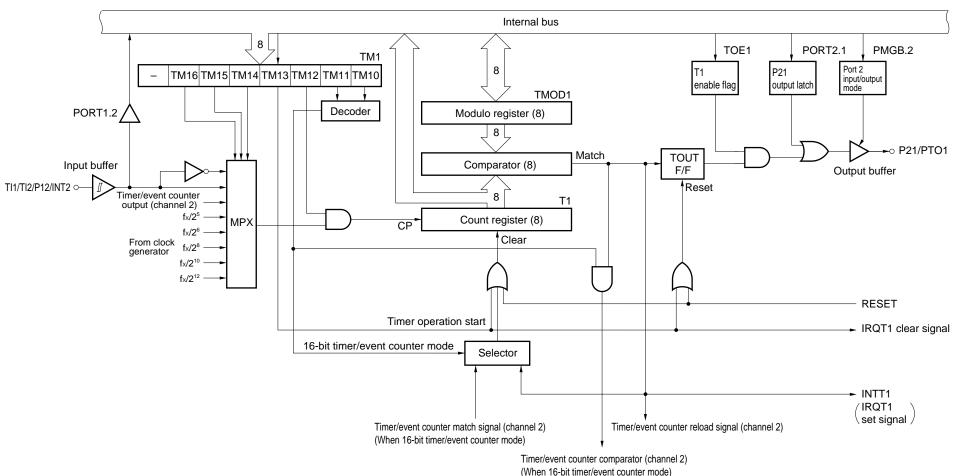




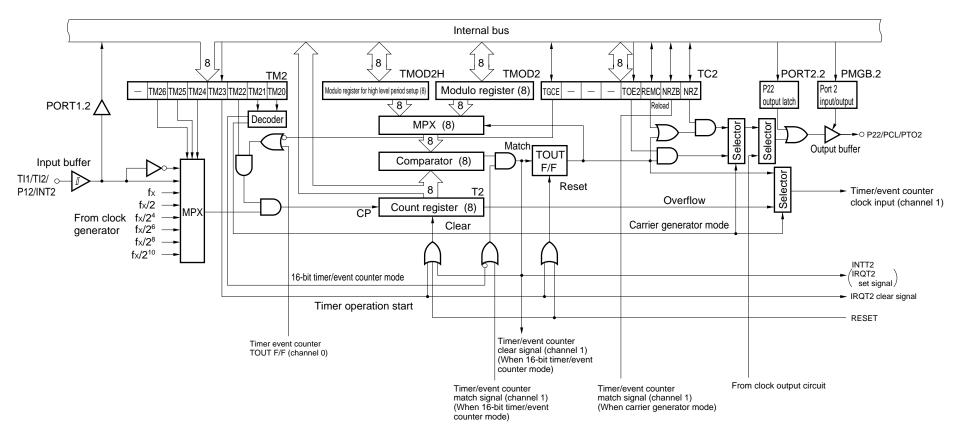
30

 $\mu$ PD753012A, 753016A, 753017A









#### 6.8 Serial Interface

The  $\mu$ PD753017A is provided with an 8-bit clocked serial interface. This serial interface operates in the following four modes:

- · Operation stop mode
- · 3-wire serial I/O mode
- · 2-wire serial I/O mode
- · SBI mode

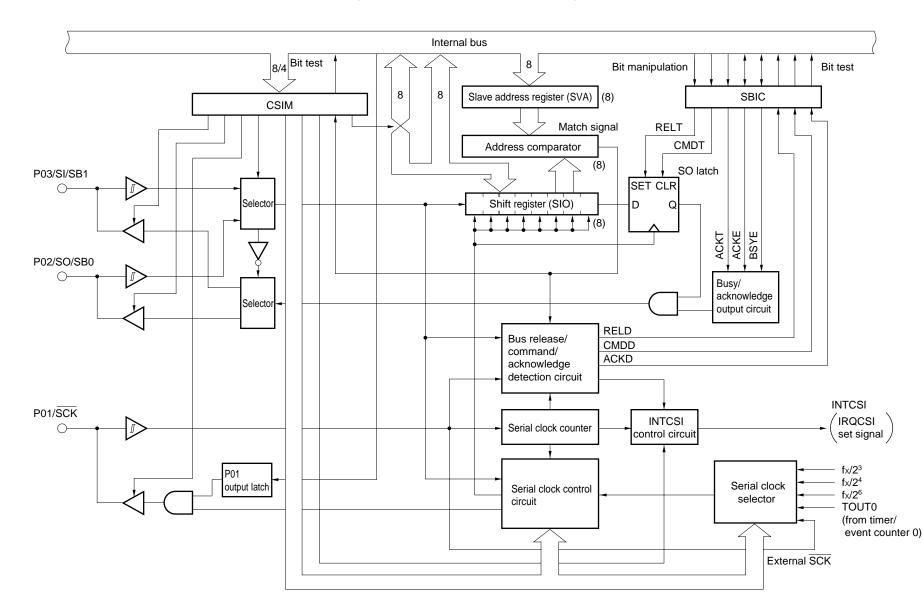


Figure 6-9. Serial Interface Block Diagram

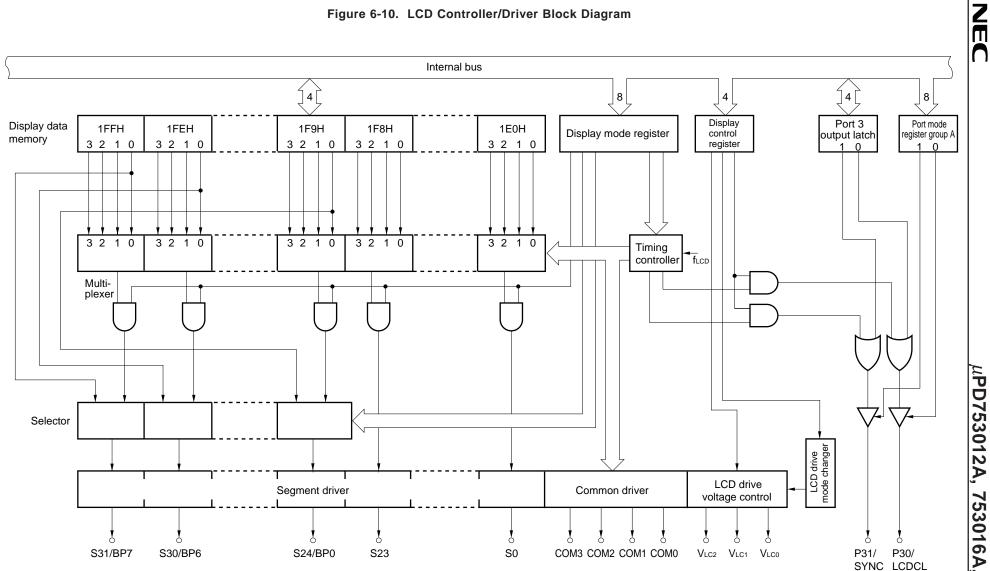
34

#### 6.9 LCD Controller/Driver

The  $\mu$ PD753017A incorporates a display controller which generates segment and common signals according to the display data memory contents and incorporates segment and common drivers which can drive the LCD panel directly.

The  $\mu$ PD753017A LCD controller/driver functions are as follows:

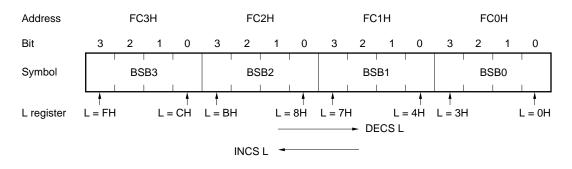
- Display data memory is read automatically by DMA operation and segment and common signals are generated.
- Display mode can be selected from among the following five:
  - <1> Static
  - $\langle 2\rangle$  1/2 duty (time multiplexing by 2), 1/2 bias
  - $\langle 3\rangle$  1/3 duty (time multiplexing by 3), 1/2 bias
  - $\langle 4 \rangle~$  1/3 duty (time multiplexing by 3), 1/3 bias
  - $\langle 5 \rangle$  1/4 duty (time multiplexing by 4), 1/3 bias
- A frame frequency can be selected from among four in each display mode.
- A maximum of 32 segment signal output pins (S0-S31) and four common signal output pins (COM0-COM3).
- The segment signal output pins (S24-S27 and S28-S31) can be changed to the output ports in 4-pin units.
- Split-resistor can be incorporated to supply LCD drive power (mask option).
  - · Various bias methods and LCD drive voltages can be applicable.
  - · When display is off, current flow to the split resistor is cut.
- Display data memory not used for display can be used for normal data memory.
- It can also operate by using the subsystem clock.



Data Sheet U11662EJ2V1DS00

# 6.10 Bit Sequential Buffer ... 16 Bits

The bit sequential buffer (BSB) is a special data memory for bit manipulation and the bit manipulation can be easily performed by changing the address specification and bit specification in sequence, therefore it is useful when processing a long data bit-wise.



#### Figure 6-11. Bit Sequential Buffer Format



2. In the pmem. @L addressing, the BSB can be manipulated regardless of MBE/MBS specification.

# 7. INTERRUPT FUNCTION AND TEST FUNCTION

 $\mu$ PD753017A has eight types of interrupt sources and two types of test sources. Among the test sources, INT2 is provided with two testable inputs for edge detection.

 $\mu$ PD753017A has the following functions in the interrupt control circuit.

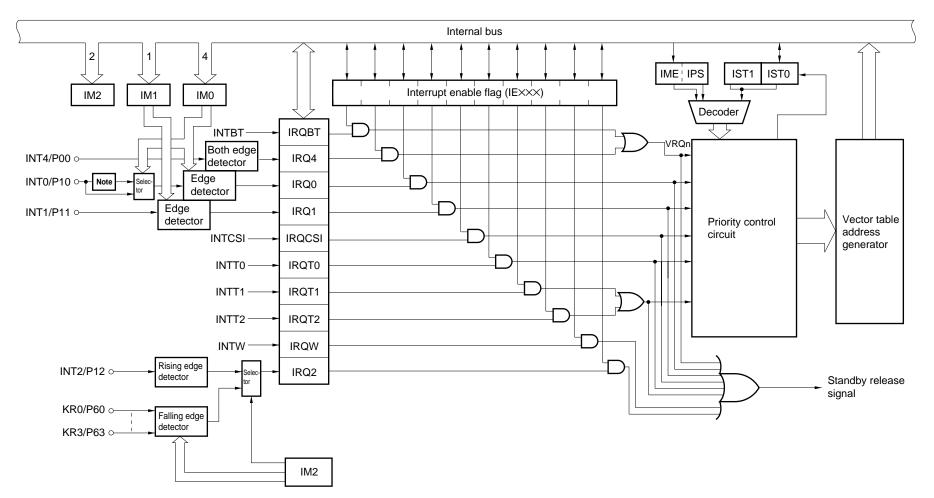
# (1) Interrupt function

- Vectored interrupt function for hardware control, enabling/disabling the interrupt acceptance by the interrupt enable flag (IEXXX) and interrupt master enable flag (IME).
- Can set any interrupt start address.
- Nesting interrupts wherein the order of priority can be specified by the interrupt priority select register (IPS).
- Test function of interrupt request flag (IRQXXX). An interrupt generated can be checked by software.
- Release the standby mode. A release interrupt can be selected by the interrupt enable flag.

# (2) Test function

- Test request flag (IRQXXX) generation can be checked by software.
- Release the standby mode. The test source to be released can be selected by the test enable flag.





Note Noise elimination circuit (Standby release is disabled when noise elimination circuit is selected.)

# 8. STANDBY FUNCTION

In order to save power consumption while a program is in a standby mode, two types of standby modes (STOP mode and HALT mode) are provided for the  $\mu$ PD753017A.

		STOP Mode	HALT Mode			
Set instruction		STOP instruction	HALT instruction			
System clo	ck when set	Settable only when the main system         Settable both by the main system           clock is used.         clock and subsystem clock.				
Operation status	Clock generator	Only the main system clock stops oscillation.	Only the CPU clock $\Phi$ halts (oscillation continues).			
	Basic interval timer/ watchdog timer	Operation stops	Operation. (The IRQBT is set in the reference interval.) <sup>Note 1</sup>			
	Serial interface	Operable only when an external SCK input is selected as the serial clock.	Operable <sup>Note 1</sup>			
	Timer/event counter	Operable only when a signal input to the TI0-TI2 pins is specified as the count clock.	Operable <sup>Note 1</sup>			
	Watch timer	Operable when fxT is selected as the count clock.	Operable			
	LCD controller/driver	Operable only when fxT is selected as the LCDCL.	Operable			
	External interrupt	The INT1, 2, and 4 are operable. Only the INT0 is not operated. <sup>Note 2</sup>				
	CPU	The operation stops.				
Release signals		<ul> <li>Interrupt request signal sent from the operable hardware enabled by the interrupt enable flag.</li> <li>Test request signal sent from the test source enabled by the test enable flag.</li> <li>RESET input</li> </ul>				

## Table 8-1. Operation Status in Standby Mode

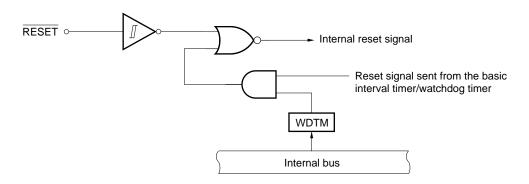
- Notes 1. Cannot operate only when the main system clock stops.
  - Can operate only when the noise elimination circuit is not used (IM02 = 1) by bit 2 of the edge detection mode register (IM0).

\*

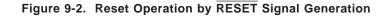
# 9. RESET FUNCTION

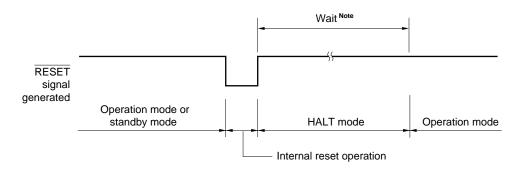
There are two reset inputs: external reset signal ( $\overline{RESET}$ ) and reset signal sent from the basic interval timer/ watchdog timer. When either one of the reset signals are input, an internal reset signal is generated. Figure 9-1 shows the circuit diagram of the above two inputs.





The  $\mu$ PD753017A is set by the RESET signal generated and each hardware is initialized as listed in Table 9-1. Figure 9-2 shows the timing chart of the reset operation.





Note The following two times can be selected by the mask option.

 $2^{17}$ /fx (21.8 ms : at 6.0 MHz operation, 31.3 ms : at 4.19 MHz operation)  $2^{15}$ /fx (5.46 ms : at 6.0 MHz operation, 7.81 ms : at 4.19 MHz operation)

		Hardware	RESET Signal Generation in Standby Mode	RESET Signal Generation in Operation
Progran	n count	er (PC)	Sets the low-order 6 bits of program memory's address 0000H to the PC13-PC8 and the contents of address 0001H to the PC7-PC0. Resets the PC14 of the $\mu$ PD753017A to 0.	Sets the low-order 6 bits of program memory's address 0000H to the PC13-PC8 and the contents of address 0001H to the PC7-PC0. Resets the PC14 of the $\mu$ PD753017A to 0.
PSW	Carry	r flag (CY)	Held	Undefined
	Skip	flag (SK0-SK2)	0	0
	Interr	upt status flag (IST0)	0	0
	Bank	enable flag (MBE, RBE)	Sets the bit 6 of program memory's address 0000H to the RBE and bit 7 to the MBE.	Sets the bit 6 of program memory's address 0000H to the RBE and bit 7 to the MBE.
Stack p	ointer (	SP)	Undefined	Undefined
Stack b	ank sel	ect register (SBS)	1000B	1000B
Data me	emory (	(RAM)	Held	Undefined
General	l-purpo	se register (X, A, H, L, D, E, B, C)	Held	Undefined
Bank se	elect re	gister (MBS, RBS)	0, 0	0, 0
Basic in	terval	Counter (BT)	Undefined	Undefined
timer/		Mode register (BTM)	0	0
watchdo	g timer	Watchdog timer enable flag (WDTM)	0	0
Timer/e	vent	Counter (T0)	0	0
counter	(T0)	Modulo register (TMOD0)	FFH	FFH
		Mode register (TM0)	0	0
		TOE0, TOUT F/F	0, 0	0, 0
Timer/e	vent	Counter (T1)	0	0
counter	(T1)	Modulo register (TMOD1)	FFH	FFH
		Mode register (TM1)	0	0
		TOE1, TOUT F/F	0, 0	0, 0
Timer/e	vent	Counter (T2)	0	0
counter	(T2)	Modulo register (TMOD2)	FFH	FFH
		High level period setting modulo register (TMOD2H)	FFH	FFH
		Mode register (TM2)	0	0
		TOE2, TOUT F/F	0, 0	0, 0
		REMC, NRZ, NRZB	0, 0, 0	0, 0, 0
		TGE	0	0
Watch t	imer	Mode register (WM)	0	0

# Table 9-1. Status of Each Hardware after Reset (1/2)

	Hardware	RESET Signal Generation in Standby Mode	RESET Signal Generation in Operation		
Serial interface	Shift register (SIO)	Held	Undefined		
	Operation mode register (CSIM)	0	0		
	SBI control register (SBIC)	0	0		
	Slave address register (SVA)	Held	Undefined		
Clock generator,	Processor clock control register (PCC)	0	0		
clock output	System clock control register (SCC)	0	0		
circuit	Clock output mode register (CLOM)	0	0		
Sub-oscillator cor	ntrol register (SOS)	0	0		
LCD controller/	Display mode register (LCDM)	0	0		
driver	Display control register (LCDC)	0	0		
Interrupt	Interrupt request flag (IRQXXX)	Reset (0)	Reset (0)		
function	Interrupt enable flag (IEXXX)	0	0		
	Interrupt master enable flag (IME)	0	0		
	INT0, 1, 2 mode registers (IM0, IM1, IM2)	0, 0, 0	0, 0, 0		
	Interrupt priority selection register (IPS)	0	0		
Digital port	Output buffer	Off	Off		
	Output latch	Cleared (0)	Cleared (0)		
	I/O mode registers (PMGA, PMGB)	0	0		
	Pull-up resistor specification register (POGA)	0	0		
Bit sequential buf	; fer (BSB0-BSB3)	Held	Undefined		

# Table 9-1. Status of Each Hardware after Reset (2/2)

# **10. MASK OPTION**

The  $\mu$ PD753017A has the following mask options.

- P40-P43, P50-P53 mask options
   On-chip pull-up resistors can be connected.
   <1> On-chip pull-up resistors are specifiable bit-wise.
   <2> On-chip pull-up resistors are not specifiable.
- VLC0-VLC2 pins, BIAS pin mask option
   On-chip split resistor for LCD drive can be connected.
  - <1> Split resistor is not connected.
  - <2> Four 10 k $\Omega$  (TYP.) split resistors are connected at the same time.
  - <3> Four 100 k $\Omega$  (TYP.) split resistors are connected at the same time.
- Standby function mask option

Wait times can be selected by a  $\overline{\text{RESET}}$  signal.

<1>  $2^{17}/fx$  (21.8 ms : at fx = 6.0 MHz, 31.3 ms : at fx = 4.19 MHz)

- <2> 2<sup>15</sup>/fx (5.46 ms : at fx = 6.0 MHz, 7.81 ms : at fx = 4.19 MHz)
- Subsystem clock mask option
   Use of the internal feedback resistor can be selected.
  - <1> Internal feedback resistor can be used. (Switched ON/OFF via software)
  - <2> Internal feedback resistor cannot be used. (Switched out in hardware)

## **11. INSTRUCTION SET**

## (1) Expression formats and description methods of operands

The operand is described in the operand column of each instruction in accordance with the description method for the operand expression format of the instruction. For details, refer to **RA75X Assembler Package User's Manual—Language (U12385E)**. If there are several elements, one of them is selected. Capital letters and the + and – symbols are key words and are described as they are. For immediate data, appropriate numbers and labels are described.

Instead of the labels such as mem, fmem, pmem, and bit, the symbols of the registers can be described.

However, there are restrictions in the labels that can be described for fmem and pmem. For details, see User's Manual.

Expression Format	Description Method
reg	X, A, B, C, D, E, H, L
reg1	X, B, C, D, E, H, L
rp	XA, BC, DE, HL
rp1	BC, DE, HL
rp2	BC, DE
rp'	XA, BC, DE, HL, XA', BC', DE', HL'
rp'1	BC, DE, HL, XA', BC', DE', HL'
rpa	HL, HL+, HL–, DE, DL
rpa1	DE, DL
n4	4-bit immediate data or label
n8	8-bit immediate data or label
mem	8-bit immediate data or label <sup>Note</sup>
bit	2-bit immediate data or label
fmem	FB0H-FBFH, FF0H-FFFH immediate data or label
pmem	FC0H-FFFH immediate data or label
addr addr1 caddr faddr	0000H-2FFFH immediate data or label (μPD753012A) 0000H-3FFFH immediate data or label (μPD753016A, 753017A) 0000H-5FFFH immediate data or label 12-bit immediate data or label 11-bit immediate data or label
taddr	20H-7FH immediate data (where bit0 = 0) or label
PORTn	PORT0-PORT7
IEXXX	IEBT, IET0-IET2, IE0-IE2, IE4, IECSI, IEW
RBn	RB0-RB3
MBn	MB0, MB1, MB2, MB3, MB15

Note mem can be only used even address in 8-bit data processing.

/	Legena	
	А	: A register; 4-bit accumulator
	В	: B register
	С	: C register
	D	: D register
	E	: E register
	Н	: H register
	L	: L register
	Х	: X register
	XA	: XA register pair; 8-bit accumulator
	BC	: BC register pair
	DE	: DE register pair
	HL	: HL register pair
	XA'	: XA' expanded register pair
	BC'	: BC' expanded register pair
	DE'	: DE' expanded register pair
	HL'	: HL' expanded register pair
	PC	: Program counter
	SP	: Stack pointer
	CY	: Carry flag; bit accumulator
	PSW	: Program status word
	MBE	: Memory bank enable flag
	RBE	: Register bank enable flag
	PORTn	: Port n (n = 0-7)
	IME	: Interrupt master enable flag
	IPS	: Interrupt priority selection register
	IEXXX	: Interrupt enable flag
	RBS	: Register bank selection register
	MBS	: Memory bank selection register
	PCC	: Processor clock control register
	•	: Separation between address and bit
	(XX)	: The contents addressed by XX
	XXH	: Hexadecimal data

# (2) Legend in explanation of operation

*1	MB = MBE•MBS		
	(MBS = 0-3, 15)		_
*2	MB = 0		
*3	MBE = 0 : MB =		
		15 (F80H-FFFH) MBS (MBS = 0-3, 15)	Data memory addressing
*4	MB = 15, fmem =	FB0H-FBFH, FF0H-FFFH	
*5	MB = 15, pmem =	= FC0H-FFFH	
*6	μPD753012A	addr = 0000H-2FFFH	
	μPD753016A 753017A	addr = 0000H-3FFFH	
*7	μPD753012A 753016A 753017A (In Mk I mode)	addr = (Current PC) - 15 to (Current PC) - 1 (Current PC) + 2 to (Current PC) + 16	
	μPD753017A (In Mk II mode)	addr1 = (Current PC) - 15 to (Current PC) - 1 (Current PC) + 2 to (Current PC) + 16	
*8	μPD753012A	caddr = 0000H-0FFFH (PC13, 12 = 00B) or 1000H-1FFFH (PC13, 12 = 01B) or 2000H-2FFFH (PC13, 12 = 10B)	
	μPD753016A	caddr = 0000H-0FFFH (PC <sub>13, 12</sub> = 00B) or 1000H-1FFFH (PC <sub>13, 12</sub> = 01B) or 2000H-2FFFH (PC <sub>13, 12</sub> = 10B) or 3000H-3FFFH (PC <sub>13, 12</sub> = 11B)	Program memory addressing
	μΡD753017A	caddr = 0000H-0FFFH (PC14, 13, 12 = 000B) or 1000H-1FFFH (PC14, 13, 12 = 001B) or 2000H-2FFFH (PC14, 13, 12 = 001B) or 3000H-3FFFH (PC14, 13, 12 = 011B) or 4000H-4FFFH (PC14, 13, 12 = 100B) or 5000H-5FFFH (PC14, 13, 12 = 101B)	
*9	faddr = 0000H-07	, /FFH	
*10	taddr = 0020H-00	)7FH	
*11	μPD753012A	addr1 = 0000H-2FFFH	
	μPD753016A	addr1 = 0000H-3FFFH	
	μPD753017A	addr1 = 0000H-5FFFH	

## (3) Explanation of symbols under addressing area column

Remarks 1. MB indicates memory bank that can be accessed.

- 2. In \*2, MB = 0 independently of how MBE and MBS are set.
- 3. In \*4 and \*5, MB = 15 independently of how MBE and MBS are set.
- 4. \*6 to \*11 indicate the areas that can be addressed.

# (4) Explanation of number of machine cycles column

S denotes the number of machine cycles required by skip operation when a skip instruction is executed. The value of S varies as follows.

- When no skip is made: S = 0
- When the skipped instruction is a 1- or 2-byte instruction: S = 1
- When the skipped instruction is a 3-byte instruction<sup>Note</sup>: S = 2

Note 3-byte instruction: BR !addr, BRA !addr1, CALL !addr or CALLA !addr1 instruction

#### Caution The GETI instruction is skipped in one machine cycle.

One machine cycle is equal to one cycle of CPU clock  $\Phi$  (= tcr); time can be selected from among four types by setting PCC.

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Transfer	MOV	A, #n4	1	1	$A \leftarrow n4$		String effect A
		reg1, #n4	2	2	reg1 ← n4		
		XA, #n8	2	2	$XA \leftarrow n8$		String effect A
		HL, #n8	2	2	$HL \leftarrow n8$		String effect B
		rp2, #n8	2	2	rp2 ← n8		
		A, @HL	1	1	$A \leftarrow (HL)$	*1	
		A, @HL+	1	2+S	$A \leftarrow (HL)$ , then $L \leftarrow L+1$	*1	L = 0
		A, @HL-	1	2+S	A $\leftarrow$ (HL), then L $\leftarrow$ L–1	*1	L = FH
		A, @rpa1	1	1	$A \leftarrow (rpa1)$	*2	
		XA, @HL	2	2	$XA \gets (HL)$	*1	
		@HL, A	1	1	$(HL) \gets A$	*1	
		@HL, XA	2	2	$(HL) \gets XA$	*1	
		A, mem	2	2	$A \leftarrow (mem)$	*3	
		XA, mem	2	2	$XA \gets (mem)$	*3	
		mem, A	2	2	(mem) ← A	*3	
		mem, XA	2	2	(mem) ← XA	*3	
		A, reg1	2	2	$A \leftarrow reg1$		
		XA, rp'	2	2	$XA \gets rp'$		
		reg1, A	2	2	$reg1 \leftarrow A$		
		rp'1, XA	2	2	rp'1 ← XA		
	ХСН	A, @HL	1	1	$A \leftrightarrow (HL)$	*1	
		A, @HL+	1	2+S	A $\leftrightarrow$ (HL), then L $\leftarrow$ L+1	*1	L = 0
		A, @HL-	1	2+S	A $\leftrightarrow$ (HL), then L $\leftarrow$ L–1	*1	L = FH
		A, @rpa1	1	1	$A \leftrightarrow (rpa1)$	*2	
		XA, @HL	2	2	$XA \leftrightarrow (HL)$	*1	
		A, mem	2	2	$A \leftrightarrow (mem)$	*3	
		XA, mem	2	2	$XA \leftrightarrow (mem)$	*3	
		A, reg1	1	1	$A \leftrightarrow reg1$		
		XA, rp'	2	2	$XA \leftrightarrow rp'$		

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Table	MOVT <sup>Note 1</sup>	XA, @PCDE	1	3	XA ← (PC <sub>13-8</sub> +DE) <sub>ROM</sub>		
reference					● μPD753017A XA ← (PC14-8+DE) <sub>ROM</sub>		
		XA, @PCXA	1	3	$XA \leftarrow (PC_{^{13-8}}\text{+}XA)_{ROM}$		
					● μPD753017A XA ← (PC14-8+XA) <sub>ROM</sub>		
		XA, @BCDE <sup>Note 2</sup>	1	3	XA ← (B1,0+CDE)ROM	*6	
					● μPD753017A XA ← (B <sub>2-0</sub> +CDE) <sub>ROM</sub>	*11	
		XA, @BCXA <sup>Note 2</sup>	1	3	$XA \leftarrow (B_{1,0}\text{+}CXA)_{\text{ROM}}$	*6	
					• $\mu$ PD753017A XA $\leftarrow$ (B <sub>2-0</sub> +CXA) <sub>ROM</sub>	*11	
Bit transfer	MOV1	CY, fmem.bit	2	2	$CY \leftarrow (fmem.bit)$	*4	
		CY, pmem.@L	2	2	$CY \leftarrow (pmem_{7-2}+L_{3-2}.bit(L_{1-0}))$	*5	
		CY, @H+mem.bit	2	2	$CY \gets (H\text{+}mem_{3\text{-}0}.bit)$	*1	
		fmem.bit, CY	2	2	$(\text{fmem.bit}) \leftarrow \text{CY}$	*4	
		pmem.@L, CY	2	2	$(pmem_{7\text{-}2}\text{+}L_{3\text{-}2}.bit(L_{1\text{-}0})) \leftarrow CY$	*5	
		@H+mem.bit, CY	2	2	(H+mem₃₋₀.bit) ← CY	*1	
Operation	ADDS	A, #n4	1	1+S	$A \leftarrow A+n4$		carry
		XA, #n8	2	2+S	$XA \leftarrow XA + n8$		carry
		A, @HL	1	1+S	$A \leftarrow A\text{+}(HL)$	*1	carry
		XA, rp'	2	2+S	$XA \leftarrow XA + rp'$		carry
		rp'1, XA	2	2+S	rp'1 ← rp'1+XA		carry
	ADDC	A, @HL	1	1	$A,CY \leftarrow A\text{+}(HL)\text{+}CY$	*1	
		XA, rp'	2	2	$XA, CY \gets XA \texttt{+} rp' \texttt{+} CY$		
		rp'1, XA	2	2	$rp'1, CY \leftarrow rp'1+XA+CY$		
	SUBS	A, @HL	1	1+S	$A \leftarrow A\text{-}(HL)$	*1	borrow
		XA, rp'	2	2+S	XA ← XA–rp'		borrow
		rp'1, XA	2	2+S	rp'1 ← rp'1–XA		borrow
	SUBC	A, @HL	1	1	$A,CY \gets A\text{-}(HL)\text{-}CY$	*1	
		XA, rp'	2	2	$XA, CY \gets XA\text{-}rp'\text{-}CY$		
		rp'1, XA	2	2	$rp'1, CY \leftarrow rp'1-XA-CY$		

**Notes 1.** The above operations in the shaded boxes can be performed only in the Mk II mode. The other operations can be performed only in the Mk I mode.

2. Only the following bits are valid for the B register.  $\mu$ PD753012A, 753016A : low-order 2 bits  $\mu$ PD753017A : low-order 3 bits

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Operation	AND	A, #n4	2	2	$A \leftarrow A \wedge n4$		
		A, @HL	1	1	$A \leftarrow A \land (HL)$	*1	
		XA, rp'	2	2	$XA \leftarrow XA \wedge rp'$		
		rp'1, XA	2	2	$rp'1 \leftarrow rp'1 \land XA$		
	OR	A, #n4	2	2	$A \leftarrow A \lor n4$		
		A, @HL	1	1	$A \leftarrow A \lor (HL)$	*1	
		XA, rp'	2	2	$XA \leftarrow XA \lor rp'$		
		rp'1, XA	2	2	$rp'1 \leftarrow rp'1 \lor XA$		
	XOR	A, #n4	2	2	A ← A ∀ n4		
		A, @HL	1	1	$A \gets A \not \forall (HL)$	*1	
		XA, rp'	2	2	$XA \leftarrow XA \; \forall \; rp'$		
		rp'1, XA	2	2	rp'1 ← rp'1 ∀ XA		
Accumulator	RORC	А	1	1	$CY \leftarrow A_0,  A_3 \leftarrow CY,  A_{n-1} \leftarrow A_n$		
manipulation	NOT	А	2	2	$A \leftarrow \overline{A}$		
Increment and	INCS	reg	1	1+S	$reg \leftarrow reg+1$		reg = 0
Decrement		rp1	1	1+S	rp1 ← rp1+1		rp1 = 00H
		@HL	2	2+S	$(HL) \leftarrow (HL)+1$	*1	(HL) = 0
		mem	2	2+S	$(\text{mem}) \leftarrow (\text{mem})\text{+}1$	*3	(mem) = 0
	DECS	reg	1	1+S	$reg \leftarrow reg-1$		reg = FH
		rp'	2	2+S	$rp' \leftarrow rp'-1$		rp' = FFH
Comparison	SKE	reg, #n4	2	2+S	Skip if reg = n4		reg = n4
		@HL, #n4	2	2+S	Skip if (HL) = n4	*1	(HL) = n4
		A, @HL	1	1+S	Skip if A = (HL)	*1	A = (HL)
		XA, @HL	2	2+S	Skip if XA = (HL)	*1	XA = (HL)
		A, reg	2	2+S	Skip if A = reg		A = reg
		XA, rp'	2	2+S	Skip if XA = rp'		XA = rp'
Carry flag manipulation	SET1	CY	1	1	$CY \leftarrow 1$		
παπιρυιατιοή	CLR1	CY	1	1	$CY \leftarrow 0$		
	SKT	CY	1	1+S	Skip if CY = 1		CY = 1
	NOT1	CY	1	1	$CY \leftarrow \overline{CY}$		

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Memory bit S manipulation	SET1	mem.bit	2	2	$(mem.bit) \leftarrow 1$	*3	
manipulation		fmem.bit	2	2	(fmem.bit) ← 1	*4	
		pmem.@L	2	2	$(pmem_{7-2}+L_{3-2}.bit(L_{1-0})) \leftarrow 1$	*5	
		@H+mem.bit	2	2	(H+mem <sub>3−0</sub> .bit) ← 1	*1	
	CLR1	mem.bit	2	2	$(mem.bit) \leftarrow 0$	*3	
		fmem.bit	2	2	(fmem.bit) $\leftarrow 0$	*4	
		pmem.@L	2	2	$(pmem_{7\cdot 2}+L_{3\cdot 2}.bit(L_{1\cdot 0}))\leftarrow 0$	*5	
		@H+mem.bit	2	2	(H+mem₃₀.bit) ← 0	*1	
	SKT	mem.bit	2	2+S	Skip if (mem.bit)=1	*3	(mem.bit)=1
		fmem.bit	2	2+S	Skip if (fmem.bit)=1	*4	(fmem.bit)=1
		pmem.@L	2	2+S	Skip if (pmem <sub>7-2</sub> +L <sub>3-2</sub> .bit(L <sub>1-0</sub> ))=1	*5	(pmem.@L)=1
		@H+mem.bit	2	2+S	Skip if (H+mem₃₋₀.bit)=1	*1	(@H+mem.bit)=1
	SKF	mem.bit	2	2+S	Skip if (mem.bit)=0	*3	(mem.bit)=0
		fmem.bit	2	2+S	Skip if (fmem.bit)=0	*4	(fmem.bit)=0
		pmem.@L	2	2+S	Skip if (pmem <sub>7-2</sub> +L <sub>3-2</sub> .bit(L <sub>1-0</sub> ))=0	*5	(pmem.@L)=0
		@H+mem.bit	2	2+S	Skip if (H+mem <sub>3-0</sub> .bit)=0	*1	(@H+mem.bit)=0
	SKTCLR	fmem.bit	2	2+S	Skip if (fmem.bit)=1 and clear	*4	(fmem.bit)=1
		pmem.@L	2	2+S	Skip if (pmem <sub>7-2</sub> +L <sub>3-2</sub> .bit(L <sub>1-0</sub> ))=1 and clear	*5	(pmem.@L)=1
		@H+mem.bit	2	2+S	Skip if (H+mem <sub>3-0</sub> .bit)=1 and clear	*1	(@H+mem.bit)=1
	AND1	CY, fmem.bit	2	2	$CY \gets CY \land (fmem.bit)$	*4	
		CY, pmem.@L	2	2	$CY \leftarrow CY \land (pmem_{72}\text{+}L_{32}.bit(L_{10}))$	*5	
		CY, @H+mem.bit	2	2	$CY \gets CY \land (H\text{+}mem_{3\text{-}0}.bit)$	*1	
	OR1	CY, fmem.bit	2	2	$CY \gets CY \lor (fmem.bit)$	*4	
		CY, pmem.@L	2	2	$CY \gets CY \lor (pmem_{72}\text{+}L_{32}.bit(L_{10}))$	*5	
		CY, @H+mem.bit	2	2	$CY \gets CY \lor (H\text{+}mem_{3\text{-}0}.bit)$	*1	
	XOR1	CY, fmem.bit	2	2	$CY \gets CY \not \forall \text{ (fmem.bit)}$	*4	
		CY, pmem.@L	2	2	$CY \gets CY \not \leftarrow (pmem_{72}\text{+}L_{32}\text{.}bit(L_{10}))$	*5	
		CY, @H+mem.bit	2	2	CY ← CY ¥ (H+mem₃₋₀.bit)	*1	

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Branch	BR <sup>Note 1</sup>	addr	_	_	PC <sub>13-0</sub> ← addr Select appropriate instruction from among the following instructions according to the assembler being used. BR !addr BRCB !caddr BR \$addr	*6	
		addr1	-	-	<ul> <li>μPD753012A, 753016A</li> <li>PC<sub>13-0</sub> ← addr1</li> <li>Select appropriate instruction from among the following instructions according to the assembler being used.</li> <li>BR !addr</li> <li>BRA !addr1</li> <li>BRCB !caddr</li> <li>BR \$addr1</li> </ul>	*11	
					<ul> <li>µPD753017A</li> <li>PC<sub>1←0</sub> ← addr1</li> <li>Select appropriate instruction from among the following instructions according to the assembler being used.</li> <li>BR !addr</li> <li>BRA !addr1</li> <li>BRCB !caddr</li> <li>BR \$addr1</li> </ul>		
		!addr	3	3	$PC_{13-0} \leftarrow addr$ • $\mu PD753017A$	*6	
					$PC_{14} \leftarrow 0, PC_{13-0} \leftarrow addr$		
		\$addr	1	2	$PC_{^{13-0}} \gets addr$	*7	
		\$addr1	1	2	● μPD753017A PC <sub>14-0</sub> ← addr1		
		PCDE	2	3	$PC_{130} \gets PC_{138}\text{+}DE$		
					● μPD753017A PC <sub>14-0</sub> ← PC <sub>14-8</sub> +DE		
		PCXA	2	3	$PC_{^{13-0}} \gets PC_{^{13-8}}\text{+}XA$		
					● μPD753017A PC <sub>14-0</sub> ← PC <sub>14-8</sub> +XA		
		BCDENote 2	2	3	PC <sub>13-0</sub> ← BCDE	*6	
					● μPD753017A PC₁₄₋₀ ← BCDE	*11	
		BCXA <sup>Note 2</sup>	2	3	$PC_{^{13-0}} \gets BCXA$	*6	
					● μPD753017A PC <sub>14-0</sub> ← BCXA	*11	

**Notes 1.** The above operations in the shaded boxes can be performed only in the Mk II mode. The other operations can be performed only in the Mk I mode.

2. Only the following bits are valid for the B register.  $\mu$ PD753012A, 753016A : low-order 2 bits  $\mu$ PD753017A : low-order 3 bits

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Branch	BRA <sup>Note</sup>	!addr	3	3	● μPD753012A, 753016A PC <sub>13-0</sub> ← addr	*6	
		!addr1	3	3	• $\mu$ PD753017A PC <sub>14-0</sub> $\leftarrow$ addr1	*11	
	BRCB <sup>Note</sup>	!caddr	2	2	$PC_{13\text{-}0} \leftarrow PC_{13,12}\text{+}caddr_{11\text{-}0}$	*8	
					● μPD753017A PC14-0 ← PC14,13,12+caddr11-0		
Subroutine stack control	CALLA <sup>Note</sup>	!addr	3	3	• $\mu$ PD753012A, 753016A (SP–6)(SP–3)(SP–4) $\leftarrow$ PC <sub>11-0</sub> (SP–5) $\leftarrow$ 0, 0, PC <sub>13, 12</sub> (SP–2) $\leftarrow \times, \times$ , MBE, RBE PC <sub>13-0</sub> $\leftarrow$ addr, SP $\leftarrow$ SP–6	*6	
		!addr1	3	3	• $\mu$ PD753017A (SP–6)(SP–3)(SP–4) $\leftarrow$ PC <sub>11-0</sub> (SP–5) $\leftarrow$ 0, PC <sub>14, 13, 12</sub> (SP–2) $\leftarrow$ ×, ×, MBE, RBE PC <sub>14-0</sub> $\leftarrow$ addr1, SP $\leftarrow$ SP–6	*11	
	CALL <sup>Note</sup>	CALL <sup>Note</sup> !addr	3	3	$\begin{array}{l} (SP-4)(SP-1)(SP-2) \leftarrow PC_{^{11-0}}\\ (SP-3) \leftarrow MBE, RBE, PC_{^{13}}, PC_{^{12}}\\ PC_{^{13-0}} \leftarrow addr, SP \leftarrow SP-4 \end{array}$	*6	
				4	• $\mu$ PD753012A, 753016A (SP-6)(SP-3)(SP-4) $\leftarrow$ PC11-0 (SP-5) $\leftarrow$ 0, 0, PC13, 12 (SP-2) $\leftarrow$ x, x, MBE, RBE PC13-0 $\leftarrow$ addr, SP $\leftarrow$ SP-6		
				4	• $\mu$ PD753017A (SP-6)(SP-3)(SP-4) $\leftarrow$ PC <sub>11-0</sub> (SP-5) $\leftarrow$ 0, PC <sub>14, 13, 12</sub> (SP-2) $\leftarrow$ ×, ×, MBE, RBE PC <sub>14</sub> $\leftarrow$ 0, PC <sub>13-0</sub> $\leftarrow$ addr, SP $\leftarrow$ SP-6		
	CALLF <sup>Note</sup>	!faddr	addr 2	2	$(SP-4)(SP-1)(SP-2) \leftarrow PC_{11-0}$ $(SP-3) \leftarrow MBE, RBE, PC_{13}, PC_{12}$ $PC_{13-0} \leftarrow 000+faddr, SP \leftarrow SP-4$	*9	
				3	• $\mu$ PD753012A, 753016A (SP-6)(SP-3)(SP-4) $\leftarrow$ PC <sub>11-0</sub> (SP-5) $\leftarrow$ 0, 0, PC <sub>13, 12</sub> (SP-2) $\leftarrow$ x, x, MBE, RBE PC <sub>13-0</sub> $\leftarrow$ 000+faddr, SP $\leftarrow$ SP-6		
				3	• $\mu$ PD753017A (SP-6)(SP-3)(SP-4) $\leftarrow$ PC <sub>11-0</sub> (SP-5) $\leftarrow$ 0, PC <sub>14, 13, 12</sub> (SP-2) $\leftarrow$ ×, ×, MBE, RBE PC <sub>14-0</sub> $\leftarrow$ 0000+faddr, SP $\leftarrow$ SP-6		

**Note** The above operations in the shaded boxes can be performed only in the Mk II mode. The other operations can be performed only in the Mk I mode.

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Subroutine stack control	RET <sup>Note</sup>		1	3	$\begin{array}{l} \text{MBE, RBE, PC}_{13}, \text{PC}_{12} \leftarrow (\text{SP+1}) \\ \text{PC}_{11-0} \leftarrow (\text{SP})(\text{SP+3})(\text{SP+2}), \\ \text{SP} \leftarrow \text{SP+4} \end{array}$		
					• $\mu$ PD753012A, 753016A ×, ×, MBE, RBE $\leftarrow$ (SP+4) 0, 0, PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2), SP $\leftarrow$ SP+6		
					• $\mu$ PD753017A ×, ×, MBE, RBE $\leftarrow$ (SP+4) 0, PC <sub>14</sub> , PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2), SP $\leftarrow$ SP+6		
	RETS <sup>Note</sup>		1	3+S	$\begin{array}{l} \text{MBE, RBE, PC}_{^{13}}, \text{PC}_{^{12}} \leftarrow (\text{SP+1}) \\ \text{PC}_{^{11-0}} \leftarrow (\text{SP})(\text{SP+3})(\text{SP+2}), \\ \text{SP} \leftarrow \text{SP+4} \\ \text{then skip unconditionally} \end{array}$		Unconditional
					• $\mu$ PD753012A, 753016A • $\chi$ , $\chi$ , MBE, RBE $\leftarrow$ (SP+4) 0, 0, PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2), SP $\leftarrow$ SP+6 then skip unconditionally		
					• $\mu$ PD753017A $x, \times$ , MBE, RBE $\leftarrow$ (SP+4) 0, PC <sub>14</sub> , PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2), SP $\leftarrow$ SP+6 then skip unconditionally		
	RETI <sup>Note</sup>	!faddr	1	3	$\begin{array}{l} \text{MBE, RBE, PC}_{13}, \text{PC}_{12} \leftarrow (\text{SP+1}) \\ \text{PC}_{11-0} \leftarrow (\text{SP})(\text{SP+3})(\text{SP+2}) \\ \text{PSW} \leftarrow (\text{SP+4})(\text{SP+5}), \text{SP} \leftarrow \text{SP+6} \end{array}$		
					• $\mu$ PD753012A, 753016A 0, 0, PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2) PSW $\leftarrow$ (SP+4)(SP+5), SP $\leftarrow$ SP+6		
					• $\mu$ PD753017A 0, PC <sub>14</sub> , PC <sub>13</sub> , PC <sub>12</sub> $\leftarrow$ (SP+1) PC <sub>11-0</sub> $\leftarrow$ (SP)(SP+3)(SP+2) PSW $\leftarrow$ (SP+4)(SP+5), SP $\leftarrow$ SP+6		

**Note** The above operations in the shaded boxes can be performed only in the Mk II mode. The other operations can be performed only in the Mk I mode.

Instruction Group	Mnemonic	Operand	Number of Bytes	Number of Machine Cycles	Operation	Addressing Area	Skip Condition
Subroutine	PUSH	rp	1	1	$(SP-1)(SP-2) \gets rp,  SP \gets SP-2$		
stack control		BS	2	2	$(SP-1) \gets MBS, (SP-2) \gets RBS, SP \gets SP-2$		
	POP	rp	1	1	$rp \leftarrow (SP+1)(SP), SP \leftarrow SP+2$		
		BS	2	2	$MBS \gets (SP+1), RBS \gets (SP), SP \gets SP+2$		
Interrupt	EI		2	2	$IME(IPS.3) \leftarrow 1$		
control		IEXXX	2	2	$IEXXX \leftarrow 1$		
	DI		2	2	$IME(IPS.3) \leftarrow 0$		
		IEXXX	2	2	$IEXXX \leftarrow 0$		
Input/output	IN <sup>Note 1</sup>	A, PORTn	2	2	$A \leftarrow PORTn$ (n = 0-7)		
		XA, PORTn	2	2	$XA \leftarrow PORTn+1, PORTn$ (n = 4, 6)		
	OUT <sup>Note 1</sup>	PORTn, A	2	2	$PORTn \leftarrow A$ (n = 2-7)		
		PORTn, XA	2	2	PORTn+1, PORTn $\leftarrow$ XA (n = 4, 6)		
CPU control	HALT		2	2	Set HALT mode (PCC.2 $\leftarrow$ 1)		
	STOP		2	2	Set STOP mode (PCC.3 $\leftarrow$ 1)		
	NOP		1	1	No operation		
Special	SEL	RBn	2	2	$RBS \leftarrow n$ (n = 0-3)		
		MBn	2	2	MBS ← n (n = 0-3, 15)		
	GETI <sup>Notes 2, 3</sup>	taddr	1	3	• When TBR instruction $PC_{13 \rightarrow 0} \leftarrow (taddr)_{5 \rightarrow 0}+(taddr+1)$	*10	
					• When TCALL instruction $(SP-4)(SP-1)(SP-2) \leftarrow PC_{11-0}$ $(SP-3) \leftarrow MBE, RBE, PC_{13}, PC_{12}$ $PC_{13-0} \leftarrow (taddr)_{5-0}+(taddr+1)$ $SP \leftarrow SP-4$		
					When instruction other than TBR and TCALL instructions (taddr) (taddr+1) instruction is executed		Depending on the reference instruction
			1	3	• $\mu$ PD753017A • When TBR instruction PC <sub>13-0</sub> $\leftarrow$ (taddr) <sub>5-0</sub> +(taddr+1) PC <sub>14</sub> $\leftarrow$ 0		
				4	• When TCALL instruction $\begin{array}{l} (SP-6)(SP-3)(SP-4) \leftarrow PC_{11-0} \\ (SP-5) \leftarrow 0, 0, PC_{13, 12} \\ (SP-2) \leftarrow \times, \times, MBE, RBE \\ PC_{13-0} \leftarrow (taddr)_{5-0}+(taddr+1) \\ SP \leftarrow SP-6, PC_{14} \leftarrow 0 \end{array}$		
				3	When instruction other than TBR and TCALL instructions (taddr) (taddr+1) instruction is executed		Depending on the reference instruction

**Notes 1.** While the IN instruction and OUT instruction are being executed, the MBE must be set to 0 or 1 and MBS must be set to 15.

- 2. The above operations in the shaded boxes can be performed only in the Mk II mode. The other operations can be performed only in the Mk I mode.
- **3.** The TBR and TCALL instructions are the table definition assembler pseudo instructions of the GETI instruction.

# 12. ELECTRICAL SPECIFICATIONS

## Absolute Maximum Ratings ( $T_A = 25^{\circ}C$ )

Parameter	Symbol		Conditions	Ratings	Unit
Supply voltage	Vdd			-0.3 to +7.0	V
Input voltage	VI1	Other	than ports 4, 5	-0.3 to V <sub>DD</sub> + 0.3	V
	V <sub>12</sub>	Ports	Pull-up resistor provided	-0.3 to V <sub>DD</sub> + 0.3	V
		4, 5	N-ch open-drain	-0.3 to +14	V
Output voltage	Vo			-0.3 to V <sub>DD</sub> + 0.3	V
High-level output current	Іон	Per pi	n	-10	mA
		Total of	of all pins	-30	mA
Low-level output current	lol	Per pi	n	30	mA
		Total of	of all pins	220	mA
Operating ambient temperature	TA			-40 to +85	°C
Storage temperature	Tstg			-65 to +150	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

## Capacitance ( $T_A = 25^{\circ}C$ , $V_{DD} = 0$ V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	CIN	f = 1 MHz			15	pF
Output capacitance	Соит	Unmeasured pins returned to 0 V			15	pF
I/O capacitance	Сю				15	pF

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Ceramic resonator	X1 X2	Oscillation frequency (f <sub>X</sub> ) <sup>Note 1</sup>		1.0		6.0 <sup>Note 2</sup>	MHz
		Oscillation stabilization time <sup>Note 3</sup>	After V <sub>DD</sub> has reached MIN. value of oscillation voltage range			4	ms
Crystal resonator	X1 X2	Oscillation frequency (fx) <sup>Note 1</sup>		1.0		6.0 <sup>Note 2</sup>	MHz
		Oscillation stabilization time <sup>Note 3</sup>	VDD = 4.5 to 5.5 V			10	ms
						30	
External clock		X1 input frequency (f <sub>X</sub> ) <sup>Note 1</sup>		1.0		6.0 <sup>Note 2</sup>	MHz
		X1 input high-, low-level width (txH, txL)		83.3		500	ns

### Main System Clock Oscillator Characteristics (TA = -40 to $+85^{\circ}$ C, V<sub>DD</sub> = 1.8 to 5.5 V)

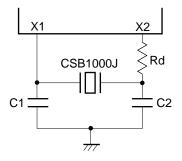
- **Notes 1.** The oscillation frequency and X1 input frequency shown above indicate characteristics of the oscillator only. For the instruction execution time, refer to **AC Characteristics**.
  - 2. If the oscillation frequency is 4.19 MHz < fx  $\leq$  6.0 MHz at 1.8 V  $\leq$  Vpd < 2.7 V, do not set the processor clock control register (PCC) to 0011. If PCC = 0011, one machine cycle time is less than 0.95  $\mu$ s, falling short of the rated value of 0.95  $\mu$ s.
  - 3. The oscillation stabilization time is the time required for oscillation to be stabilized after VDD has been applied or STOP mode has been released.
- Caution When using the main system clock oscillator, wire the portion enclosed in the dotted line in the above figure as follows to prevent adverse influence due to wiring capacitance:
  - Keep the wiring length as short as possible.
  - · Do not cross the wiring with other signal lines.
  - Do not route the wiring in the vicinity of a line through which a high alternating current flows.
  - Always keep the ground point of the capacitor of the oscillator at the same potential as VDD.
  - Do not ground to a power supply pattern through which a high current flows.
  - Do not extract signals from the oscillator.

## **Recommended Oscillator Constant**

# Ceramic resonator (T<sub>A</sub> = -20 to $+80^{\circ}$ C)

Manufacturer	Part Number	Frequency (MHz)	Recommen Consta	ided Circuit int (pF)		n Voltage ge (V)	Remarks
			C1	C2	MIN.	MAX.	
TDK Corp.	CCR1000K2	1.0	100	100	1.8	5.5	-
	CCR2.0MC33	2.0	_	-			On-chip capacitor
	CCR4.19MC3	4.19					
	FCR4.19MC5						
	CCR6.0MC3	6.0					
Murata Mfg.	CSB1000J <sup>Note</sup>	1.0	100	100	2.1	5.5	Rd = 5.6 kΩ
Co., Ltd.	CSA2.00MG040	2.0	100	100	1.9		_
	CST2.00MG040		_	_			On-chip capacitor
	CSA4.19MG	4.19	30	30	1.8		-
	CST4.19MGW		_	_			On-chip capacitor
	CSA6.00MG	6.0	30	30	2.3		-
	CST6.00MGW		_	_			On-chip capacitor
Kyocera Corp.	KBR-1000F/Y	1.0	100	100	1.8	5.5	-
	KBR-2.0MS	2.0	68	68			
	KBR-4.0MSA/MSB	4.0	33	33			
	KBR-4.0MKC		_	_			On-chip capacitor
	KBR-4.0MKD						
	KBR-4.0MKS						
	PBRC4.00A	4.0	33	33			-
	PBRC4.00B	-	_	-			On-chip capacitor
	KBR-4.19MSA	4.19	33	33			-
	KBR-4.19MSB		33	33			
	KBR-4.19MKC		_	-			On-chip capacitor
	KBR-4.19MKD	-					
	KBR-4.19MKS	-					
	PBRC4.19A	-	33	33			-
	PBRC4.19B		_	_			On-chip capacitor
	KBR-6.0MSA/MSB	6.0	33	33			_
	KBR-6.0MKC		_	_			On-chip capacitor
	KBR-6.0MKD	]					
	KBR-6.0MKS						
	PBRC6.00A		33	33			_
	PBRC6.00B	]	_	_			On-chip capacitor

**Note** When using the CSB1000J (1.0 MHz) by Murata Mfg. Co., Ltd. as a ceramic resonator, a limiting resistor (Rd =  $5.6 \text{ k}\Omega$ ) is necessary (refer to the figure below). The resistor is not necessary when using the other recommended resonators.



Caution The oscillator constant and oscillation voltage range indicate conditions of stable oscillation. Oscillation frequency precision is not guaranteed. For applications requiring oscillation frequency precision, the oscillation frequency must be adjusted on the implementation circuit. For details, please contact directly the manufacturer of the resonator you will use.

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Crystal resonator	XT1 XT2	Oscillation frequency (f <sub>XT</sub> ) <sup>Note 1</sup>		32	32.768	35	kHz
		Oscillation stabilization time <sup>Note 2</sup>	V <sub>DD</sub> = 4.5 to 5.5 V		1.0	2	S
	VDD					10	
External clock		XT1 input frequency (f <sub>XT</sub> ) <sup>Note 1</sup>		32		100	kHz
	Å	XT1 input high-, low-level width (tхтн, tхт∟)		5		15	μs

### Subsystem Clock Oscillator Characteristics ( $T_A = -40$ to $+85^{\circ}C$ , $V_{DD} = 1.8$ to 5.5 V)

- **Notes 1.** The oscillation frequency shown above indicates characteristics of the oscillator only. For the instruction execution time, refer to **AC Characteristics**.
  - 2. The oscillation stabilization time is the time required for oscillation to be stabilized after VDD has been applied.
- Caution When using the subsystem clock oscillator, wire the portion enclosed in the dotted line in the above figure as follows to prevent adverse influence due to wiring capacitance:
  - · Keep the wiring length as short as possible.
  - · Do not cross the wiring with other signal lines.
  - Do not route the wiring in the vicinity of a line through which a high alternating current flows.
  - Always keep the ground point of the capacitor of the oscillator at the same potential as VDD.
  - Do not ground to a power supply pattern through which a high current flows.
  - Do not extract signals from the oscillation circuit.

The subsystem clock oscillator has a low amplification factor to reduce current consumption and is more susceptible to noise than the main system clock oscillator. Therefore, exercise utmost care in wiring the subsystem clock oscillator.

★ Remark For the resonator selection and oscillator constant, customers are requested to either evaluate the oscillation themselves or apply to the resonator manufacturer for evaluation.

# DC Characteristics (TA = -40 to +85°C, VDD = 1.8 to 5.5 V)

Parameter	Symbol		Condition	6	MIN.	TYP.	MAX.	Unit
Low-level output	lo∟	Per pin					15	mA
current		Total of all	pins				150	mA
High-level input	VIH1	Ports 2, 3		VDD = 2.7 to 5.5 V	0.7 Vdd		Vdd	V
voltage				VDD = 1.8 to 2.7 V	0.9 Vdd		Vdd	V
	VIH2	Ports 0, 1,	6, 7, RESET	VDD = 2.7 to 5.5 V	0.8 Vdd		Vdd	V
				VDD = 1.8 to 2.7 V	0.9 Vdd		Vdd	V
	Vінз	Ports 4, 5	Pull-up resistor	VDD = 2.7 to 5.5 V	0.7 Vdd		Vdd	V
			provided	VDD = 1.8 to 2.7 V	0.9 Vdd		Vdd	V
			N-ch open-drain	VDD = 2.7 to 5.5 V	0.7 Vdd		13	V
				VDD = 1.8 to 2.7 V	0.9 Vdd		13	V
	VIH4	X1, XT1			Vdd-0.1		Vdd	V
Low-level input	VIL1	Ports 2, 3,	4, 5	VDD = 2.7 to 5.5 V	0		0.3 Vdd	V
voltage				VDD = 1.8 to 2.7 V	0		0.1 Vdd	V
	VIL2	Ports 0, 1,	6, 7, RESET	VDD = 2.7 to 5.5 V	0		0.2 Vdd	V
				VDD = 1.8 to 2.7 V	0		0.1 Vdd	V
	VIL3	X1, XT1		I	0		0.1	V
High-level output voltage	Vон		Ports 2, 3, 6, 7, BP	0-BP7 Іон = -1 mA	Vdd-0.5			V
Low-level output	Vol1	SCK, SO, F	Ports 2-7,	lo∟ = 15 mA		0.2	2.0	V
voltage		BP0-BP7		Vdd = 5.0 V ±10%				
C C				lo∟ = 1.6 mA			0.4	V
	Vol2	SB0, SB1	N-ch open-drain	I			0.2 Vdd	V
			Pull-up resistor ≥	1 kΩ				
High-level input	Ілн1	Vin = Vdd	Pins other than X	1, XT1, ports 4, 5			3	μA
leakage current	ILIH2		X1, XT1				20	μA
-	Ілнз	VIN = 13 V	Ports 4, 5 (N-ch	open-drain)			20	μA
Low-level input	ILIL1	$V_{IN} = 0 V$	Pins other than X	1, XT1, ports 4, 5			-3	μA
leakage current	LIL2		X1, XT1				-20	μA
U U	ILIL3		Ports 4, 5 (N-ch o	open-drain)			-3	μA
				iction is not executed				,
			Ports 4, 5 (N-ch				-30	μA
			open-drain)	Vdd = 5 V		-10	-27	μA
			When input	VDD = 3 V		-3	-8	μA
			instruction is					
			executed					
High-level output	ILOH1	Vout = Vdd		B1, ports 2, 3, 6, 7,			3	μA
leakage current				resistor provided),				,
-			BP0-BP7	. ,,				
	ILOH2	Vout = 13 V	Ports 4, 5 (N-ch	open-drain)			20	μA
Low-level output	ILOL	Vout = 0 V		. ,			-3	μA
leakage current								
Internal pull-up	RL1	$V_{IN} = 0 V$	Ports 0, 1, 2, 3, 6	6, 7 (except P00 pin)	50	100	200	kΩ
resistor	RL2		Ports 4, 5 (mask		15	30	60	kΩ

 $\star$ 

Parameter	Symbol		Co	onditions		MIN.	TYP.	MAX.	Unit
LCD drive	VLCD	VAC0 = 0				2.2		Vdd	V
voltage <sup>Note 1</sup>		VAC0 = 1				1.8		Vdd	V
VAC currentNote 2	IVAC	VAC0 = 1,	VDD = 2.0 V	/ ±10%			1	4	μΑ
LCD split	RLCD1						100	200	kΩ
resistor <sup>Note 3</sup>	RLCD2					5	10	20	kΩ
LCD output voltage	Vodc	lo =	VLCD0 = V	LCD		0		±0.2	V
deviation <sup>Note 4</sup>		±1.0 μA	VLCD1 = V	LCD $ imes$ 2/3					
(common)			VLCD2 = V	LCD $ imes$ 1/3					
LCD output voltage	Vods	lo =	1.8 V ≤ V	$_{\rm LCD} \leq V_{\rm DD}$		0		±0.2	V
deviation <sup>Note 4</sup>		±0.5 μA							
(segment)									
Supply	IDD1	6.00 MHz <sup>Note 6</sup>	VDD = 5.0	V ±10% <sup>Not</sup>	e 7		2.2	6.6	mA
current <sup>Notes 2, 5</sup>		crystal oscillation	VDD = 3.0	V ±10% <sup>Not</sup>	e 8		0.6	2.0	mA
	IDD2	C1 = C2	HALT	VDD = 5.0	V ±10%		0.72	2.1	mA
		= 22 pF	mode	VDD = 3.0	V ±10%		0.27	0.8	mA
	IDD1	4.19 MHz <sup>Note 6</sup>	VDD = 5.0	V ±10% <sup>Not</sup>	e 7		1.7	5.1	mA
		crystal oscillation	VDD = 3.0	V ±10% <sup>Not</sup>	e 8		0.3	0.9	mA
	IDD2	C1 = C2	HALT	VDD = 5.0	V ±10%		0.7	2.0	mA
		= 22 pF	mode	VDD = 3.0	V ±10%		0.23	0.7	mA
	Іддз	32.768	Low	VDD = 3.0	V ±10%		15	45	μA
		kHz <sup>Note 9</sup>	voltage	VDD = 2.0	V ±10%		8	24	μΑ
		crystal	mode <sup>Note 10</sup>	VDD = 3.0	V, T <sub>A</sub> = 25°C		15	30	μΑ
		oscillation	Low current	VDD = 3.0	V ±10%		12	36	μΑ
			consumption mode <sup>Note 11</sup>	VDD = 3.0	V, $T_A = 25^{\circ}C$		12	24	μA
	IDD4		HALT	Low	$V_{DD} = 3.0 \text{ V} \pm 10\%$		8.5	25	μA
			mode	voltage	VDD = 2.0 V ±10%		4	12	μA
				mode <sup>Note 10</sup>	$V_{DD} = 3.0 V, T_A = 25^{\circ}C$		8.5	17	μA
				Low current	$V_{DD} = 3.0 \text{ V} \pm 10\%$		3.5	12	μA
				consumption mode <sup>Note 11</sup>	$V_{DD} = 3.0 V, T_A = 25^{\circ}C$		3.5	7	μA
	Idd5	XT1 =	VDD = 5.0	V ±10%			0.05	10	μA
		0 V <sup>Note 12</sup>	VDD = 3.0	V ±10%			0.02	5	μA
		STOP mode			$T_A = 25^{\circ}C$		0.02	3	μA

## DC Characteristics (T<sub>A</sub> = -40 to $+85^{\circ}$ C, V<sub>DD</sub> = 1.8 to 5.5 V)

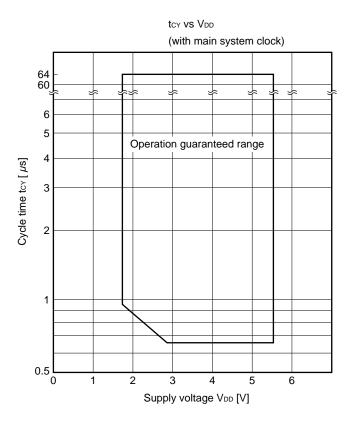
**Notes 1.** When  $1.8 \text{ V} \le \text{V}_{\text{DD}} < 2.7 \text{ V}$ ,  $T_{\text{A}} = -10 \text{ to } +85^{\circ}\text{C}$ .

- 2. Clear VAC0 to 0 in the low current consumption mode and STOP mode. When VAC0 is set to 1, the current increases by about 1  $\mu$ A.
- 3. Either RLCD1 or RLCD2 can be selected by mask option.
- **4.** Voltage deviation is the difference between the ideal values (VLCDn; n = 0, 1, 2) of the segment and common outputs and the output voltage.
- 5. The current flowing through the internal pull-up resistor and the LCD divider resistor is not included.
- 6. Including the case when the subsystem clock oscillates.
- 7. When the device operates in high-speed mode with the processor clock control register (PCC) set to 0011.
- 8. When the device operates in low-speed mode with PCC set to 0000.
- **9.** When the device operates on the subsystem clock, with the system clock control register (SCC) set to 1001 and oscillation of the main system clock stopped.
- **10.** When the sub-oscillator control register (SOS) is set to 0000.
- 11. When SOS is set to 0010.
- **12.** When SOS is set to 00X1, and the feedback resistor of the sub-oscillator is not used (X: don't care).

Parameter	Symbol	Cond	itions	MIN.	TYP.	MAX.	Unit
CPU clock cycle time <sup>Note 1</sup>	tcy	Operates with	V <sub>DD</sub> = 2.7 to 5.5 V	0.67		64	μs
(minimum instruction		main system clock		0.95		64	μs
execution time = 1		Operates with		114	122	125	μs
machine cycle)		subsystem clock					
TI0, TI1, TI2 input frequency	fтı	VDD = 2.7 to 5.5 \	/	0		1	MHz
				0		275	kHz
TI0, TI1, TI2 input high-,	t⊤iH, t⊤i∟	VDD = 2.7 to 5.5 \	/	0.48			μs
low-level width				1.8			μs
Interrupt input high-,	tinth, tintl	INT0	IM02 = 0	Note 2			μs
low-level width			IM02 = 1	10			μs
		INT1, 2, 4		10			μs
		KR0-KR7		10			μs
RESET low-level width	trsl			10			μs

# AC Characteristics (TA = -40 to +85°C, VDD = 1.8 to 5.5 V)

- Notes 1. The cycle time of the CPU clock (Φ) is determined by the oscillation frequency of the connected resonator, the system clock control register (SCC), and processor clock control register (PCC). The figure on the right shows the supply voltage VDD vs. cycle time tcy characteristics when the device operates with the main system clock.
  - 2. 2tcy or 128/fx depending on the setting of the interrupt mode register (IM0).



#### Serial transfer operation

# 2-wire and 3-wire serial I/O modes ( $\overline{SCK}$ ... internal clock output): (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SCK cycle time	<b>t</b> ксү1	V <sub>DD</sub> = 2.7 to 5.5 V	1300			ns
			3800			ns
SCK high-, low-level width	tĸ∟1	V <sub>DD</sub> = 2.7 to 5.5 V	tксү1/2-50			ns
	tкнı		tксү1/2–150			ns
SI <sup>Note 1</sup> setup time	tsik1	V <sub>DD</sub> = 2.7 to 5.5 V	150			ns
(to SCK ↑)			500			ns
SI <sup>Note 1</sup> hold time	tksi1	V <sub>DD</sub> = 2.7 to 5.5 V	400			ns
(from SCK ↑)			600			ns
$\overline{SCK} \downarrow \to SO^{Note 1}$	tkso1	$R_{L} = 1 \ k\Omega$ , Note 2 $V_{DD} = 2.7 \ to \ 5.5 \ V$	0		250	ns
output delay time		C <sub>L</sub> = 100 pF	0		1000	ns

Notes 1. Read as SB0 or SB1 when using the 2-wire serial I/O mode.

2. RL and CL respectively indicate the load resistance and load capacitance of the SO output line.

## 2-wire and 3-wire serial I/O modes ( $\overline{SCK}$ ... external clock input): (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SCK cycle time	tксү2	V <sub>DD</sub> = 2.7 to 5.5 V	800			ns
			3200			ns
SCK high-, low-level width	tĸl2	VDD = 2.7 to 5.5 V	400			ns
	<b>t</b> кн2		1600			ns
SI <sup>Note 1</sup> setup time	tsik2	V <sub>DD</sub> = 2.7 to 5.5 V	100			ns
(to SCK ↑)			150			ns
SI <sup>Note 1</sup> hold time	tksi2	V <sub>DD</sub> = 2.7 to 5.5 V	400			ns
(from SCK ↑)			600			ns
$\overline{SCK} \downarrow \to SO^{Note 1}$	tkso2	$R_L = 1 \ k\Omega$ , Note 2 $V_{DD} = 2.7 \ to \ 5.5 \ V$	0		300	ns
output delay time		CL = 100 pF	0		1000	ns

Notes 1. Read as SB0 or SB1 when using the 2-wire serial I/O mode.

2. RL and CL respectively indicate the load resistance and load capacitance of the SO output line.

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
SCK cycle time	tксүз	V <sub>DD</sub> = 2.7 to 5.5 V		1300			ns
				3800			ns
SCK high-, low-level width	tкьз	VDD = 2.7 to 5.5 V	/	tксүз/2–50			ns
	tкнз			tксүз/2–150			ns
SB0, 1 setup time	tsiкз	VDD = 2.7 to 5.5 V	/	150			ns
(to SCK ↑)				500			ns
SB0, 1 hold time (from $\overline{SCK} \uparrow$ )	tหรเง			tксүз/2			ns
$\overline{SCK}\downarrow \to SB0, 1 \text{ output}$	tкsoз	$R_{L} = 1 \ k\Omega$ , Note	V <sub>DD</sub> = 2.7 to 5.5 V	0		250	ns
delay time		C∟ = 100 pF		0		1000	ns
$\overline{SCK} \uparrow \to SB0, \ 1 \downarrow$	tкsв			tксүз			ns
SB0, 1 $\downarrow \rightarrow \overline{\text{SCK}} \downarrow$	tsвк			tксүз			ns
SB0, 1 low-level width	tsвL			tксүз			ns
SB0, 1 high-level width	tsвн			tксүз			ns

# SBI mode ( $\overline{SCK}$ … internal clock output (master)): (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

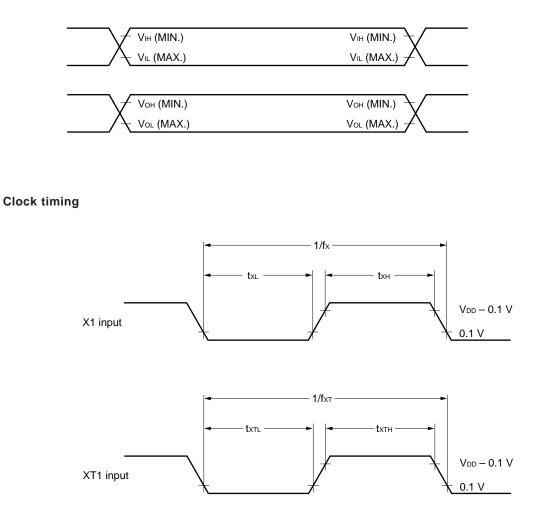
Note RL and CL respectively indicate the load resistance and load capacitance of the SB0, 1 output line.

# SBI mode (SCK --- external clock input (slave)): (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

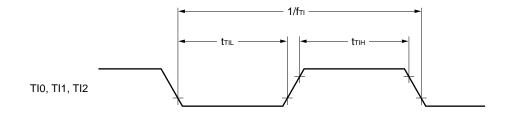
Parameter	Symbol	Cond	MIN.	TYP.	MAX.	Unit	
SCK cycle time	tксү4	V <sub>DD</sub> = 2.7 to 5.5 V		800			ns
				3200			ns
SCK high-, low-level width	tĸ∟4	VDD = 2.7 to 5.5 \	/	400			ns
	tкн4			1600			ns
SB0, 1 setup time	tsik4	V <sub>DD</sub> = 2.7 to 5.5 V		100			ns
(to SCK ↑)				150			ns
SB0, 1 hold time (from $\overline{SCK} \uparrow$ )	tksi4			tксү4/2			ns
$\overline{SCK} \downarrow \rightarrow SB0, 1 \text{ output}$	tkso4	$R_{L} = 1 \ k\Omega$ , Note	V <sub>DD</sub> = 2.7 to 5.5 V	0		300	ns
delay time		C∟ = 100 pF		0		1000	ns
$\overline{SCK} \uparrow \to SB0, 1 \downarrow$	tкsв			tксү4			ns
SB0, 1 $\downarrow \rightarrow \overline{\text{SCK}} \downarrow$	tsвк			tксү4			ns
SB0, 1 low-level width	tsвL			tксү4			ns
SB0, 1 high-level width	tsвн			tkcy4			ns

**Note** RL and CL respectively indicate the load resistance and load capacitance of the SB0, 1 output line.

# AC timing test points (except X1 and XT1 inputs)

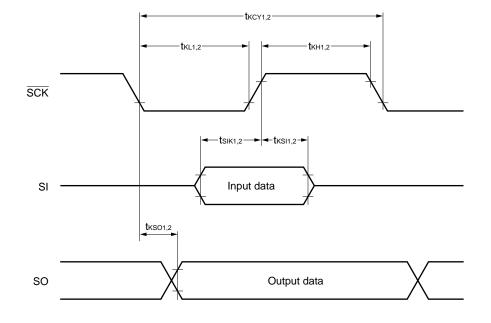


TI0, TI1, TI2 timing

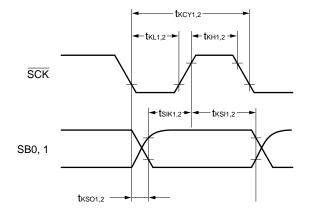


# Serial transfer timing

# 3-wire serial I/O mode

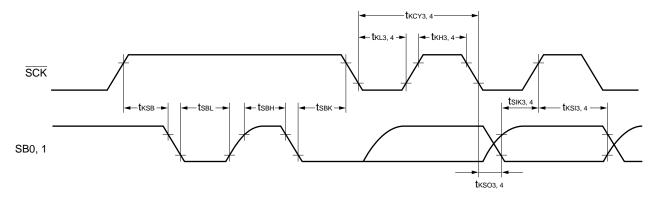


# 2-wire serial I/O mode

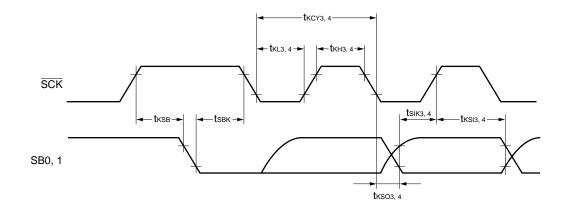


# Serial transfer timing

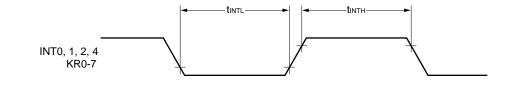
# Bus release signal transfer



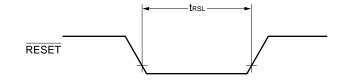
# Command signal transfer



# Interrupt input timing



# **RESET** input timing



# Data retention characteristics of data memory in STOP mode and at low supply voltage (T<sub>A</sub> = -40 to +85°C)

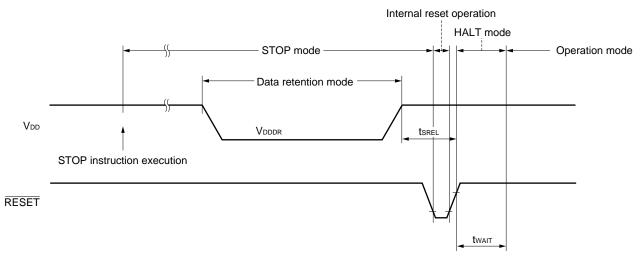
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*	Data retention power supply voltage	Vdddr		1.8		5.5	V
	Release signal setup time	tsrel		0			μs
	Oscillation stabilization	twait	Released by RESET		Note 2		ms
	wait time <sup>Note 1</sup>		Released by interrupt request		Note 3		ms

**Notes 1.** The oscillation stabilization wait time is the time during which the CPU stops operating to prevent unstable operation when oscillation is started.

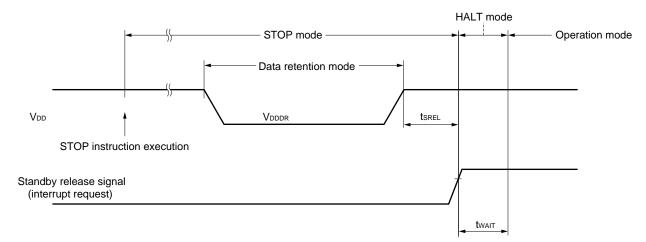
- 2. Either  $2^{17}/fx$  or  $2^{15}/fx$  can be selected by mask option.
- 3. Set by the basic interval timer mode register (BTM). (Refer to the table below.)

втмз	BTM2	BTM2 BTM1	BTM0	Wait Time			
DINIS			DINU	fx = 4.19 MHz	fx = 6.0  MHz		
_	0	0	0	2 <sup>20</sup> /fx (approx. 250 ms)	2 <sup>20</sup> /fx (approx. 175 ms)		
-	0	1	1	217/fx (approx. 31.3 ms)	2 <sup>17</sup> /fx (approx. 21.8 ms)		
-	1	0	1	2 <sup>15</sup> /fx (approx. 7.81 ms)	2 <sup>15</sup> /fx (approx. 5.46 ms)		
_	1	1	1	2 <sup>13</sup> /fx (approx. 1.95 ms)	2 <sup>13</sup> /fx (approx. 1.37 ms)		

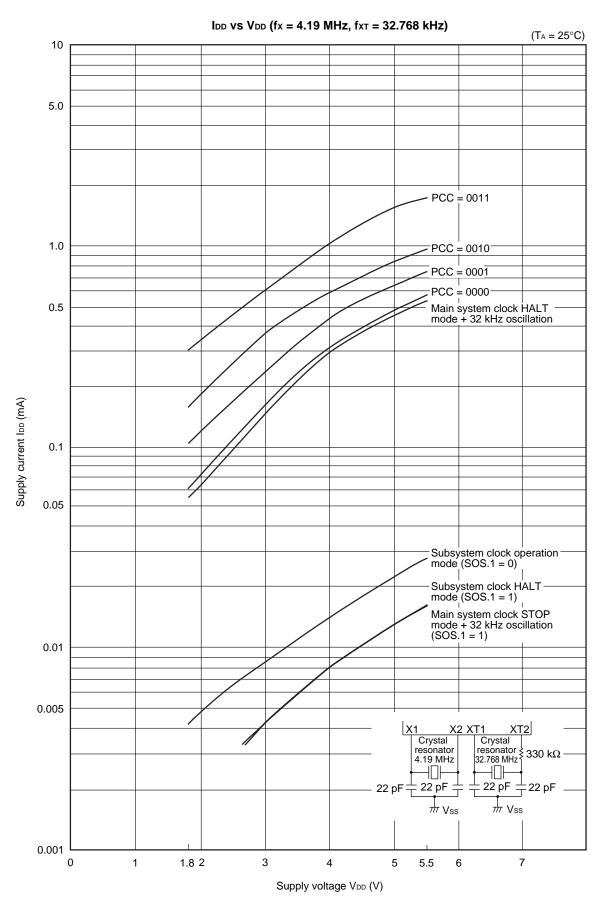
# Data retention timing (when STOP mode released by RESET)

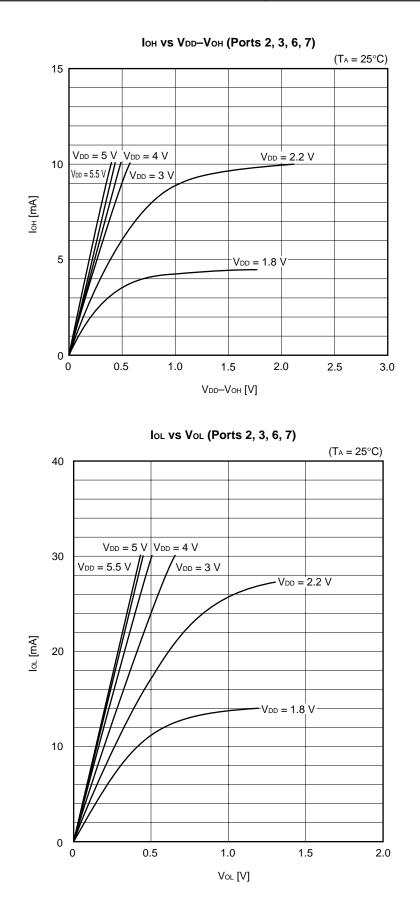


## Data retention timing (standby release signal: when STOP mode released by interrupt signal)



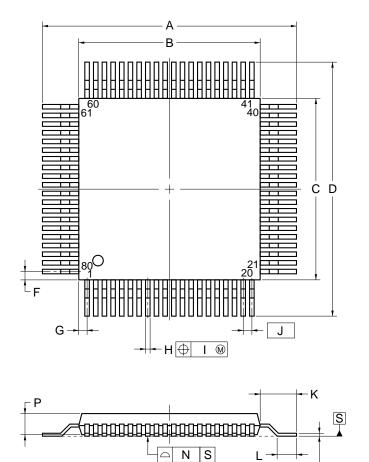
13. CHARACTERISTICS CURVES (REFERENCE VALUES)

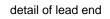


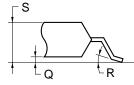


14. PACKAGE DRAWINGS

# 80-PIN PLASTIC QFP (14x14)





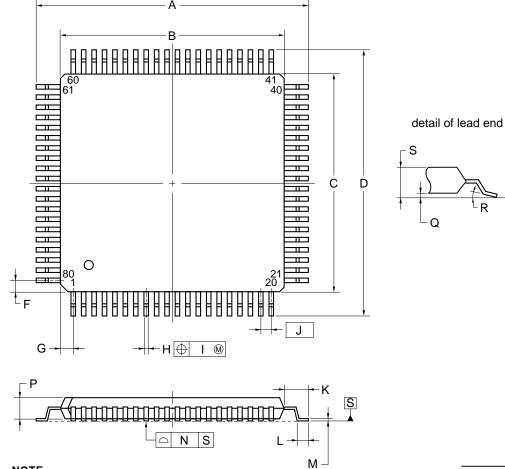


Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
А	17.2±0.4
В	14.0±0.2
С	14.0±0.2
D	17.2±0.4
F	0.825
G	0.825
Н	0.30±0.10
I	0.13
J	0.65 (T.P.)
К	1.6±0.2
L	0.8±0.2
М	$0.15\substack{+0.10 \\ -0.05}$
N	0.10
P	2.7±0.1
Q	0.1±0.1
R	5°±5°
S	3.0 MAX.
	S80GC-65-3B9-6

Μ

\* 80-PIN PLASTIC QFP (14x14)

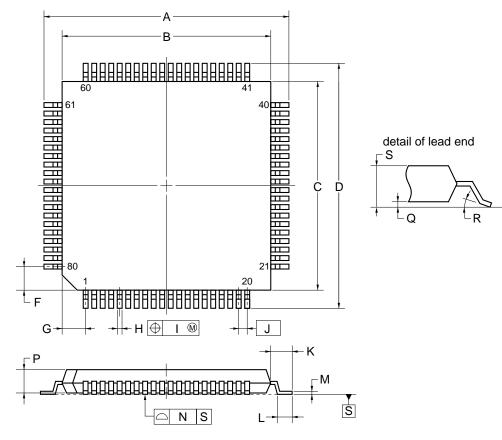


#### NOTE

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	17.20±0.20
В	14.00±0.20
С	14.00±0.20
D	17.20±0.20
F	0.825
G	0.825
Н	0.32±0.06
I	0.13
J	0.65 (T.P.)
К	1.60±0.20
L	0.80±0.20
М	$0.17\substack{+0.03 \\ -0.07}$
Ν	0.10
Р	1.40±0.10
Q	0.125±0.075
R	3° <sup>+7°</sup> -3°
S	1.70 MAX.
	P80GC-65-8BT-1

# 80 PIN PLASTIC TQFP (FINE PITCH) (12x12)

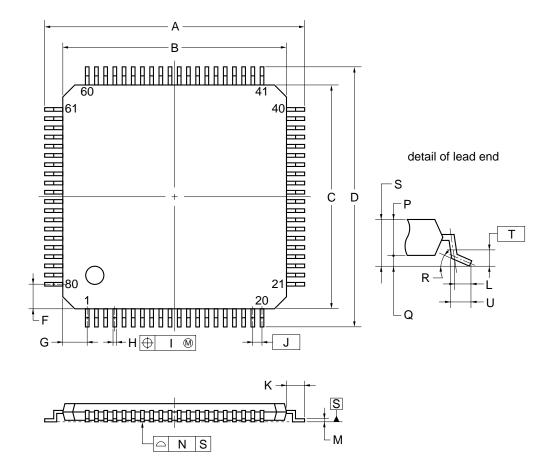


#### NOTE

Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
А	14.00±0.20
В	12.00±0.20
С	12.00±0.20
D	14.00±0.20
F	1.25
G	1.25
Н	$0.22^{+0.05}_{-0.04}$
I	0.10
J	0.50 (T.P.)
К	1.00±0.20
L	0.50±0.20
М	$0.145^{+0.055}_{-0.045}$
Ν	0.10
Р	1.05±0.07
Q	0.10±0.05
R	5°±5°
S	1.27 MAX.
	P80GK-50-BE9-6

★ 80-PIN PLASTIC TQFP (FINE PITCH) (12x12)



# NOTE

Each lead centerline is located within 0.08 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
Α	14.0±0.2
В	12.0±0.2
С	12.0±0.2
D	14.0±0.2
F	1.25
G	1.25
Н	0.22±0.05
I	0.08
J	0.5 (T.P.)
К	1.0±0.2
L	0.5
М	0.145±0.05
Ν	0.08
Р	1.0
Q	0.1±0.05
R	$3^{\circ + 4^{\circ}}_{-3^{\circ}}$
S	1.1±0.1
Т	0.25
U	0.6±0.15
	P80GK-50-9EU-1

## **15. RECOMMENDED SOLDERING CONDITIONS**

Solder the  $\mu$ PD753017A under the following recommended conditions.

For the details on the recommended soldering conditions, refer to Information Document **Semiconductor Device Mounting Technology Manual (C10535E)**.

For the soldering methods and conditions other than those recommended, consult NEC.

#### Table 15-1. Soldering Conditions of Surface Mount Type (1/2)

(1)  $\mu$ PD753012AGC-XXX-3B9: 80-pin plastic QFP (14 × 14 mm, resin thickness 2.7 mm)  $\mu$ PD753016AGC-XXX-3B9: 80-pin plastic QFP (14 × 14 mm, resin thickness 2.7 mm)  $\mu$ PD753017AGC-XXX-3B9: 80-pin plastic QFP (14 × 14 mm, resin thickness 2.7 mm)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or below (210°C or higher), Number of reflow processes: 3 max.	IR35-00-3
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or below (200°C or higher), Number of reflow processes: 3 max.	VP15-00-3
Wave soldering	Solder temperature: 260°C or below, Time: 10 seconds or below, Number of flow processes: 1 Preheating temperature: 120°C or below (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C or below, Time: 3 seconds or below (per side of device)	_

(2)  $\mu$ PD753012AGC-XXX-8BT: 80-pin plastic QFP (14 × 14 mm, resin thickness 1.4 mm)  $\mu$ PD753016AGC-XXX-8BT: 80-pin plastic QFP (14 × 14 mm, resin thickness 1.4 mm)  $\mu$ PD753017AGC-XXX-8BT: 80-pin plastic QFP (14 × 14 mm, resin thickness 1.4 mm)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or below (210°C or higher), Number of reflow processes: 2 max.	IR35-00-2
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or below (200°C or higher), Number of reflow processes: 2 max.	VP15-00-2
Wave soldering	Solder temperature: 260°C or below, Time: 10 seconds or below, Number of flow processes: 1 Preheating temperature: 120°C or below (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C or below, Time: 3 seconds or below (per side of device)	-

Caution Do not use two or more soldering methods in combination (except the partial heating method).

#### Table 15-1. Soldering Conditions of Surface Mount Type (2/2)

# (3) $\mu$ PD753012AGK-XXX-BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.05 mm) $\mu$ PD753016AGK-XXX-BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.05 mm) $\mu$ PD753017AGK-XXX-BE9: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.05 mm)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or below (210°C or higher), Number of reflow processes: 3 max., Exposure limit: 7 days <sup>Note</sup> (After that, prebaking is necessary at 125°C for 10 hours.)	IR35-107-3
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or below (200°C or higher), Number of reflow processes: 3 max., Exposure limit: 7 days <sup>Note</sup> (After that, prebaking is necessary at 125°C for 10 hours.)	VP15-107-3
Partial heating	Pin temperature: 300°C or below, Time: 3 seconds or below (per side of device)	-

**Note** The number of days for storage after the dry pack has been opened. The storage conditions are 25°C, 65% RH max.

 (4) μPD753012AGK-XXX-9EU: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.00 mm) μPD753016AGK-XXX-9EU: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.00 mm) μPD753017AGK-XXX-9EU: 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.00 mm)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Reflow time: 30 seconds or below (210°C or higher), Number of reflow processes: 2 max., Exposure limit: 7 days <sup>Note</sup> (After that, prebaking is necessary at 125°C for 10 hours.)	IR35-107-2
VPS	Package peak temperature: 215°C, Reflow time: 40 seconds or below (200°C or higher), Number of reflow processes: 2 max., Exposure limit: 7 days <sup>Note</sup> (After that, prebaking is necessary at 125°C for 10 hours.)	VP15-107-2
Partial heating	Pin temperature: 300°C or below, Time: 3 seconds or below (per side of device)	_

**Note** The number of days for storage after the dry pack has been opened. The storage conditions are 25°C, 65% RH max.

Caution Do not use two or more soldering methods in combination (except the partial heating method).

# APPENDIX A. $\mu\text{PD75316B},753017\text{A}$ and 75P3018A function list

	Parameter	μPD75316B	μPD753017A	μPD75P3018A	
Program memory		Mask ROM 0000H-3F7FH (16256 × 8 bits)	Mask ROM 0000H-5FFFH (24576 × 8 bits)	One-time PROM 0000H-7FFFH (32768 × 8 bits)	
Data memory		000H-3FFH (1024 × 4 bits)			
CPU		75X Standard	75XL CPU		
Instruction execution	When main system clock is selected	0.95, 1.91, 15.3 μs (at 4.19 MHz operation)	<ul> <li>0.95, 1.91, 3.81, 15.3 μs (at 4.19 MHz operation)</li> <li>0.67, 1.33, 2.67, 10.7 μs (at 6.0 MHz operation)</li> </ul>		
time	When subsystem clock is selected	122 μs (32.768 kHz operation)			
Pin	44	P12/INT2	P12/INT2/TI1/TI2		
connection	47	P21	P21/PTO1		
	48	P22/PCL	P22/PCL/PTO2		
	50-53	P30-P33		P30/MD0-P33/MD3	
	57	IC		Vpp	
Stack	SBS register	None	SBS.3 = 1: Mk I mode selection SBS.3 = 0: Mk II mode selection		
	Stack area	000H-0FFH	n00H-nFFH (n = 0-3)		
	Subroutine call instruction stack operation	2-byte stack	Mk I mode: 2-byte stack Mk II mode: 3-byte stack		
Instruction	BRA !addr1 CALLA !addr1	Unavailable	Mk I mode: unavailable Mk II mode: available		
	MOVT XA, @BCDE MOVT XA, @BCXA BR BCDE BR BCXA		Available		
	CALL !addr	3 machine cycles	Mk I mode: 3 machine cycles, Mk II mode: 4 machine cycles		
	CALLF !faddr	2 machine cycles	Mk I mode: 2 machine cycles, Mk II mode: 3 machine cycles		
Timer		3 channels • Basic interval timer: 1 channel • 8-bit timer/event counter: 1 channel • Watch timer: 1 channel	<ul> <li>5 channels</li> <li>Basic interval timer/watchdog timer: 1 channel</li> <li>8-bit timer/event counter: 3 channels (can be used as 16-bit timer/event counter, carrier generator, timer with gate)</li> <li>Watch timer: 1 channel</li> </ul>		

	Parameter	μPD75316B	μPD753017A	μPD75P3018A
Clock output (PCL)		Φ, 524, 262, 65.5 kHz (Main system clock: at 4.19 MHz operation)	<ul> <li>Φ, 524, 262, 65.5 kHz (Main system clock: at 4.19 MHz operation)</li> <li>Φ, 750, 375, 93.8 kHz (Main system clock: at 6.0 MHz operation)</li> </ul>	
BUZ output       2 kHz (Main system clock: at 4.19 MHz operation)       • 2, 4, 32 kHz (Main system clock: at 4.19 MHz operation o subsystem clock: at 32.768 kHz operation)         • 2, 9, 35, 86, 46.9 kHz (Main system clock: at 6.0 MHz operation)		Hz operation)		
Serial interface 3 modes are available • 3-wire serial I/O mode MSB/LSB can • 2-wire serial I/O mode • SBI mode		B/LSB can be selected for transfer	first bit	
SOS Feedback resistor cut flag register (SOS.0)		None	Provided	
	Sub-oscillator current cut flag (SOS.1)	None	Provided	
Register I	bank selection register (RBS)	None	Yes	
Standby r	release by INT0	Unavailable	Available	
Interrupt priority selection register (IPS)		None	Yes	
Vectored interrupt		External: 3, internal: 3	External: 3, internal: 5	
Supply voltage		V <sub>DD</sub> = 2.0 to 6.0 V V <sub>DD</sub> = 1.8 to 5.5 V		
Operating ambient temperature		$T_A = -40$ to $+85^{\circ}C$		
Package		<ul> <li>80-pin plastic TQFP (fine pitch) (12 × 12 mm)</li> <li>80-pin plastic QFP (14 × 14 mm)</li> </ul>		

# APPENDIX B. DEVELOPMENT TOOLS

The following development tools are provided for system development using the  $\mu$ PD753017A. The 75XL series uses a common relocatable assembler, in combination with a device file matching each machine.

#### Language processor

RA75X relocatable assembler	Host Machine	OS	Supply modia	Part Number (product name)
		03	Supply media	(product hamo)
	PC-9800 series	MS-DOS™	3.5-inch 2HD	μS5A13RA75X
		Ver. 3.30 to		
		Ver. 6.2 <sup>Note</sup>		
	IBM PC/AT™ and	Refer to	3.5-inch 2HC	μS7B13RA75X
	compatible machines	OS for IBM PC		

Device file	Host Machine	OS	Supply media	Part Number (product name)
		03	Supply media	([)
	PC-9800 series	MS-DOS	3.5-inch 2HD	μS5A13DF753017
		/ Ver. 3.30 to		
		Ver. 6.2 <sup>Note</sup>		
	IBM PC/AT and	Refer to	3.5-inch 2HC	μS7B13DF753017
	compatible machines	OS for IBM PC		

Note Ver. 5.00 or later is provided with a task swap function, but it does not work with this software.

**Remark** The operation of the assembler and device file is guaranteed only on the above host machines and OSs.

\*

\*

#### **PROM** write tools

	Hardware	PG-1500	<ul> <li>PG-1500 is a PROM programmer which enables you to program single-chip microc containing PROM by stand-alone or host machine operation by connecting an a board and optional programmer adapter to PG-1500.</li> <li>It also enables you to program typical PROM devices of 256K bits to 4M bits.</li> </ul>				
		PA-75P316BGC	PROM programmer adapter to PG-1500 f	75P3018AGC-3B9. Co	nnect the programmer		
		PA-75P316BGK	PROM programmer adapter common to $\mu$ PD75P3018AGK-BE9. Connect the programmer adapter to PG-1500 for use.				
r		PA-75P3018AGC-8BT	PROM programmer adapter common to $\mu$ PD75P3018AGC-8BT. Connect the programmer adapter to PG-1500 for use.				
r.		PA-75P3018AGK-9EU	PROM programmer adapter common to $\mu$ PD75P3018AGK-9EU. Connect the programmer adapter to PG-1500 for use.				
	Software	PG-1500 controller	PG-1500 and a host machine are connected by serial and parallel i is controlled on the host machine.			terfaces and PG-1500	
			Host machine			Part number	
			riost machine	OS	Supply media	(product name)	
			PC-9800 series	MS-DOS	3.5-inch 2HD	μS5A13PG1500	
				Ver. 3.30 to Ver. 6.2 <sup>Note</sup>			
			IBM PC/AT and compatible machines	Refer to OS for IBM PC	3.5-inch 2HD	μS7B13PG1500	

**Note** Ver.5.00 or later is provided with a task swap function, but it does not work with this software.

**Remark** The operation of the PG-1500 controller is guaranteed only on the above host machines and OSs.

#### **Debugging tool**

The in-circuit emulators (IE-75000-R and IE-75001-R) are available as the program debugging tool for the  $\mu$ PD753017A.

The system configurations are described as follows.

Hardware	IE-75000-R <sup>Note 1</sup>	In-circuit emulator for debugging the hardware and software when developing the application systems that use the 75X series and 75XL series. When developing a $\mu$ PD753017 subseries, the emulation board IE-75300-R-EM and emulation probe that are sold separately must be used with the IE-75000-R. By connecting with the host machine and the PROM programmer, efficient debugging can be made. It contains the emulation board IE-75000-R-EM which is connected.			
	IE-75001-R	In-circuit emulator for debugging the hardware and software when developing the application systems that use the 75X series and 75XL series. When developing a $\mu$ PD753017 subseries, the emulation board IE-75300-R-EM and emulation probe which are sold separately must be used with the IE-75001-R. It can debug the system efficiently by connecting the host machine and PROM programmer.			
	IE-75300-R-EM	Emulation probe for the μPD753017AGK.         It must be connected to the IE-75000-R (or IE-75001-R) and IE-75300-R-EM.         It is supplied with the 80-pin conversion adapter TGK-080SDW which facilitates			PD753017 subseries.
	EP-753017GC-R				
	EP-753017GK-R TGK-080SDW <sup>Note 2</sup>				
Software	IE control program	Connects the IE-75000-R or IE-75001-R to a host machine via RS-232-C and Centronix I/F and controls the IE-75000-R or IE-75001-R on a host machine.			
		Host machine	OS	Supply media	Part number (product name)
		PC-9800 series	MS-DOS Ver. 3.30 to Ver. 6.2 <sup>Note 3</sup>	3.5-inch 2HD	μS5A13IE75X
		IBM PC/AT and compatible machines	Refer to OS for IBM PC	3.5-inch 2HC	μ\$7B13IE75X

#### Notes 1. Maintenance parts

- 2. This is a product of TOKYO ELETECH CORPORATION.
  - For further information, contact: Daimaru Kogyo, Ltd.

Tokyo Electronics Department (TEL +81-3-3820-7112)

Osaka Electronics 2nd Department (TEL +81-6-6244-6672)

**3.** Ver.5.00 or later is provided with a task swap function, but it dose not work with this software.

**Remarks 1.** The operation of the IE control program is guaranteed only on the above host machines and OSs.

**2.** The μPD753012, 753016, 753017, 75P3018, 753012A, 753016A, 753017A, and 75P3018A are commonly referred to as the μPD753017 subseries.

# OS for IBM PC

The following IBM PC OS's are supported.

OS	Version
PC DOS™	Ver. 5.02 to Ver. 6.3 J6.1/V <sup>Note</sup> to J6.3/V <sup>Note</sup>
MS-DOS	Ver. 5.0 to Ver. 6.22 5.0/V <sup>Note</sup> to 6.2/V <sup>Note</sup>
IBM DOS™	J5.02/V <sup>Note</sup>

**Note** Only English version is supported.

Caution Ver. 5.0 or later is provided with a task swap function, but it does not work with this software.

#### \*

# APPENDIX C. RELATED DOCUMENTS

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

# **Device Related Documents**

Document Name	Document No.		
	Japanese	English	
μPD753012A, 753016A, 753017A Data Sheet	U11662J	U11662E (this document)	
μPD75P3018A Data Sheet	U11917J	U11917E	
μPD753017 User's Manual	U11282J	U11282E	
µPD753017 Instruction Table	IEM-5598	_	
75XL Series Selection Guide	U10453J	U10453E	

#### **Development Tool Related Documents**

Document Name			Document No.	
Document Name		Japanese	English	
Hardware	Hardware IE-75000-R/IE-75001-R User's Manual IE-75300-R-EM User's Manual EP-753017GC/GK-R User's Manual PG-1500 User's Manual		EEU-846	EEU-1416
			U11354J	U11354E
			EEU-967	EEU-1494
			U11940J	U11940E
Software	RA75X Assembler Package	Operation	U12622J	U12622E
	User's Manual	Language	U12385J	U12385E
	PG-1500 Controller User's Manual	PC-9800 Series (MS-DOS) Base	EEU-704	EEU-1291
		IBM PC Series (PC DOS) Base	EEU-5008	U10540E

#### **Other Related Documents**

Document Name	Document No.	
Document Name	Japanese	English
SEMICONDUCTOR SELECTION GUIDE Products & Package (CD-ROM)	Products & Package (CD-ROM) X13769X	
Semiconductor Device Mounting Technology Manual	C10535J	C10535E
Quality Grades on NEC Semiconductor Devices	C11531J	C11531E
NEC Semiconductor Device Reliability/Quality Control System	C10983J	C10983E
Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD)	C11892J	C11892E
Guide to Microcontroller-Related Products by Third Parties	U11416J	_

Caution The above related documents are subject to change without notice. For design purpose, etc., be sure to use the latest documents.

# – NOTES FOR CMOS DEVICES –

## **①** PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

#### Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

#### **②** HANDLING OF UNUSED INPUT PINS FOR CMOS

#### Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

#### **③** STATUS BEFORE INITIALIZATION OF MOS DEVICES

#### Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

# **Regional Information**

Some information contained in this document may vary from country to country. Before using any NEC product in your application, please contact the NEC office in your country to obtain a list of authorized representatives and distributors. They will verify:

- Device availability
- Ordering information
- Product release schedule
- · Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- Network requirements

In addition, trademarks, registered trademarks, export restrictions, and other legal issues may also vary from country to country.

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